



## CY7C1566V18, CY7C1577V18 CY7C1568V18, CY7C1570V18

# 72-Mbit DDR-II+ SRAM 2-Word Burst Architecture (2.5 Cycle Read Latency)

## Features

- 72-Mbit density (8M x 8, 8M x 9, 4M x 18, 2M x 36)
- 400 MHz clock for high bandwidth
- 2-word burst for reducing address bus frequency
- Double Data Rate (DDR) interfaces  
(data transferred at 800 MHz) at 400 MHz
- Available in 2.5 clock cycle latency
- Two input clocks (K and  $\bar{K}$ ) for precise DDR timing
  - SRAM uses rising edges only
- Echo clocks (CQ and  $\bar{CQ}$ ) simplify data capture in high-speed systems
- Data valid pin (QVLD) to indicate valid data on the output
- Synchronous internally self-timed writes
- Core  $V_{DD} = 1.8V \pm 0.1V$ ; IO  $V_{DDQ} = 1.4V$  to  $V_{DD}$  <sup>[1]</sup>
- HSTL inputs and variable drive HSTL output buffers
- Available in 165-Ball FBGA package (15 x 17 x 1.4 mm)
- Offered in both Pb-free and non Pb-free packages
- JTAG 1149.1 compatible test access port
- Delay Lock Loop (DLL) for accurate data placement

## Configurations

### With Read Cycle Latency of 2.5 cycles:

CY7C1566V18 – 8M x 8

CY7C1577V18 – 8M x 9

CY7C1568V18 – 4M x 18

CY7C1570V18 – 2M x 36

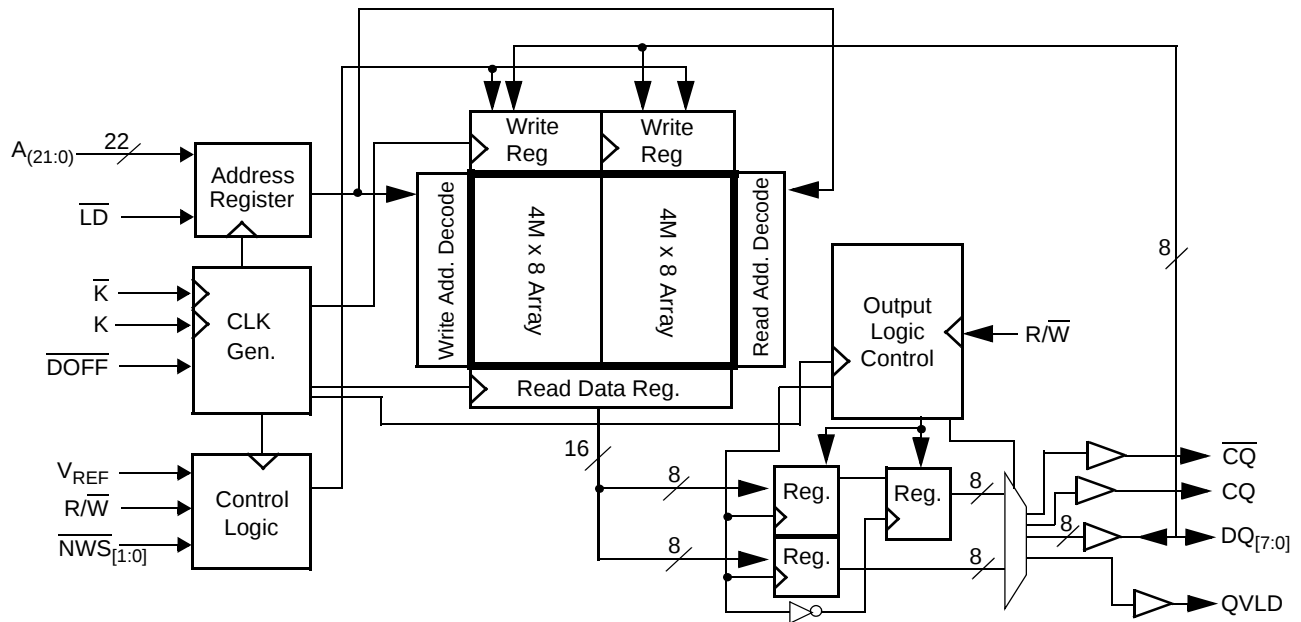
## Selection Guide

| Description                 |     | 400 MHz | 375 MHz | 333 MHz | 300 MHz | Unit |
|-----------------------------|-----|---------|---------|---------|---------|------|
| Maximum Operating Frequency |     | 400     | 375     | 333     | 300     | MHz  |
| Maximum Operating Current   | x8  | 1400    | 1300    | 1200    | 1100    | mA   |
|                             | x9  | 1400    | 1300    | 1200    | 1100    |      |
|                             | x18 | 1400    | 1300    | 1200    | 1100    |      |
|                             | x36 | 1400    | 1300    | 1200    | 1100    |      |

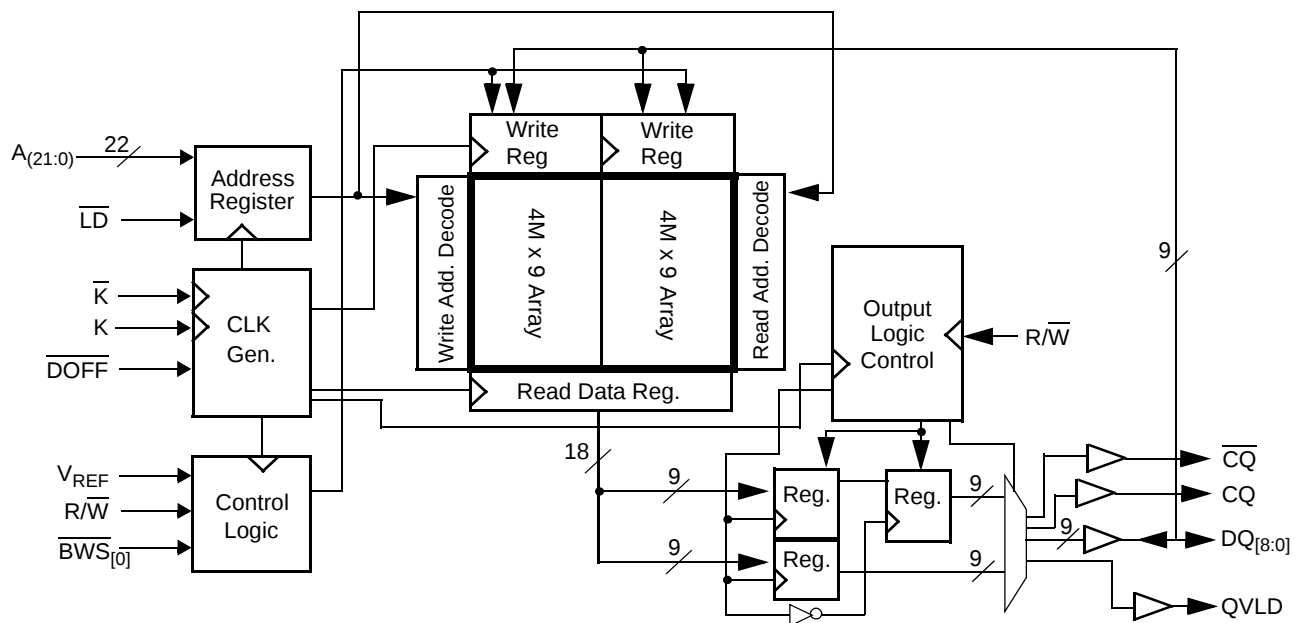
### Note

1. The QDR consortium specification for  $V_{DDQ}$  is  $1.5V \pm 0.1V$ . The Cypress QDR devices exceed the QDR consortium specification and are capable of supporting  $V_{DDQ} = 1.4V$  to  $V_{DD}$ .

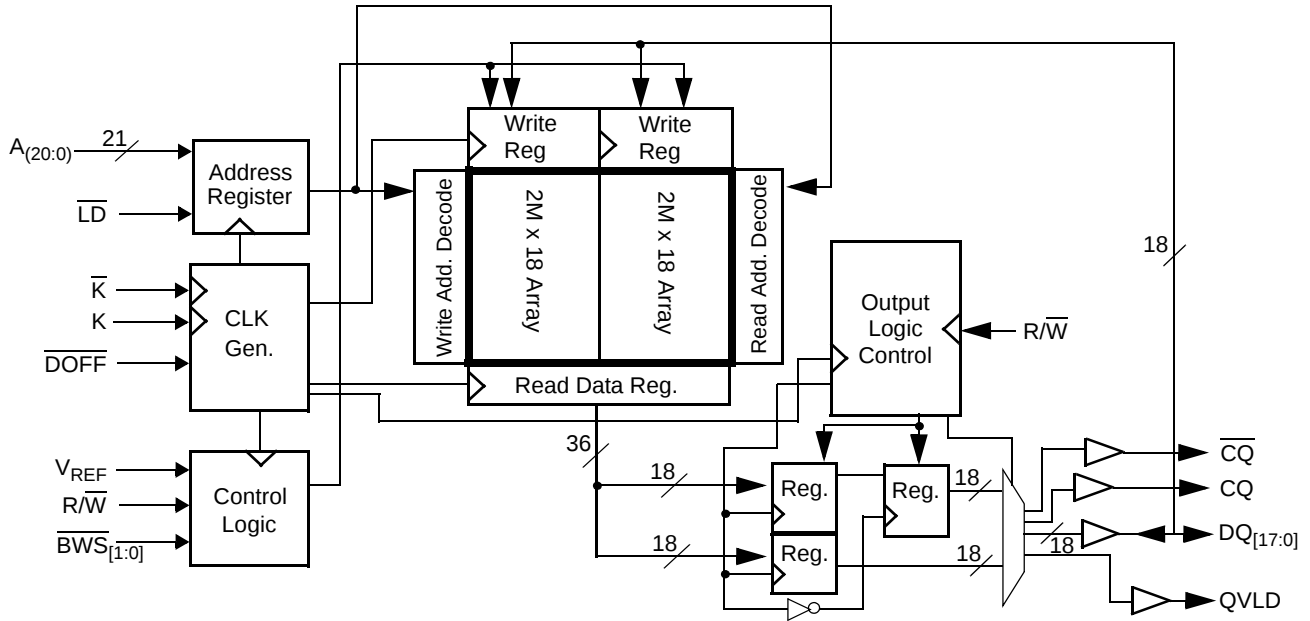
## Logic Block Diagram (CY7C1566V18)



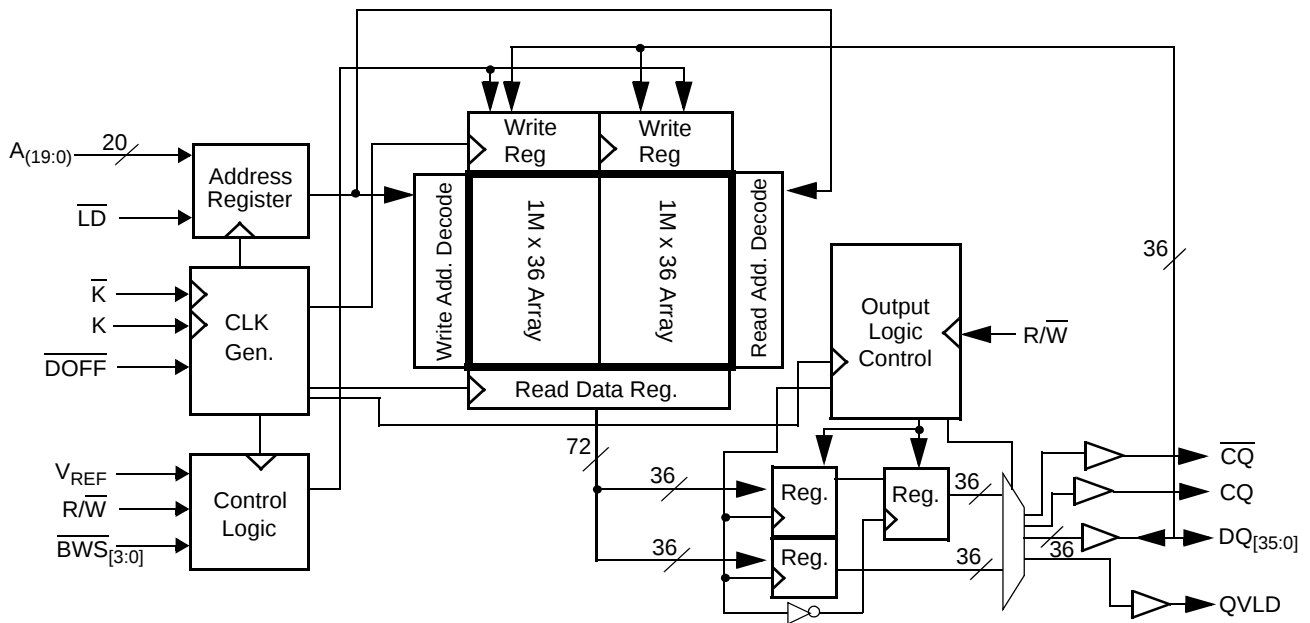
## Logic Block Diagram (CY7C1577V18)



## Logic Block Diagram (CY7C1568V18)



## Logic Block Diagram (CY7C1570V18)



## Pin Configuration

The pin configuration for CY7C1566V18, CY7C1577V18, CY7C1568V18, and CY7C1570V18 follow. [2]

### 165-Ball FBGA (15 x 17 x 1.4 mm) Pinout

#### CY7C1566V18 (8M x 8)

|          | 1                        | 2                | 3                | 4                              | 5                         | 6                     | 7                         | 8                      | 9                | 10               | 11  |
|----------|--------------------------|------------------|------------------|--------------------------------|---------------------------|-----------------------|---------------------------|------------------------|------------------|------------------|-----|
| <b>A</b> | $\overline{\text{CQ}}$   | A                | A                | $\text{R}/\overline{\text{W}}$ | $\overline{\text{NWS}}_1$ | $\overline{\text{K}}$ | NC/144M                   | $\overline{\text{LD}}$ | A                | A                | CQ  |
| <b>B</b> | NC                       | NC               | NC               | A                              | NC/288M                   | K                     | $\overline{\text{NWS}}_0$ | A                      | NC               | NC               | DQ3 |
| <b>C</b> | NC                       | NC               | NC               | $V_{\text{SS}}$                | A                         | A                     | A                         | $V_{\text{SS}}$        | NC               | NC               | NC  |
| <b>D</b> | NC                       | NC               | NC               | $V_{\text{SS}}$                | $V_{\text{SS}}$           | $V_{\text{SS}}$       | $V_{\text{SS}}$           | $V_{\text{SS}}$        | NC               | NC               | NC  |
| <b>E</b> | NC                       | NC               | DQ4              | $V_{\text{DDQ}}$               | $V_{\text{SS}}$           | $V_{\text{SS}}$       | $V_{\text{SS}}$           | $V_{\text{DDQ}}$       | NC               | NC               | DQ2 |
| <b>F</b> | NC                       | NC               | NC               | $V_{\text{DDQ}}$               | $V_{\text{DD}}$           | $V_{\text{SS}}$       | $V_{\text{DD}}$           | $V_{\text{DDQ}}$       | NC               | NC               | NC  |
| <b>G</b> | NC                       | NC               | DQ5              | $V_{\text{DDQ}}$               | $V_{\text{DD}}$           | $V_{\text{SS}}$       | $V_{\text{DD}}$           | $V_{\text{DDQ}}$       | NC               | NC               | NC  |
| <b>H</b> | $\overline{\text{DOFF}}$ | $V_{\text{REF}}$ | $V_{\text{DDQ}}$ | $V_{\text{DDQ}}$               | $V_{\text{DD}}$           | $V_{\text{SS}}$       | $V_{\text{DD}}$           | $V_{\text{DDQ}}$       | $V_{\text{DDQ}}$ | $V_{\text{REF}}$ | ZQ  |
| <b>J</b> | NC                       | NC               | NC               | $V_{\text{DDQ}}$               | $V_{\text{DD}}$           | $V_{\text{SS}}$       | $V_{\text{DD}}$           | $V_{\text{DDQ}}$       | NC               | DQ1              | NC  |
| <b>K</b> | NC                       | NC               | NC               | $V_{\text{DDQ}}$               | $V_{\text{DD}}$           | $V_{\text{SS}}$       | $V_{\text{DD}}$           | $V_{\text{DDQ}}$       | NC               | NC               | NC  |
| <b>L</b> | NC                       | DQ6              | NC               | $V_{\text{DDQ}}$               | $V_{\text{SS}}$           | $V_{\text{SS}}$       | $V_{\text{SS}}$           | $V_{\text{DDQ}}$       | NC               | NC               | DQ0 |
| <b>M</b> | NC                       | NC               | NC               | $V_{\text{SS}}$                | $V_{\text{SS}}$           | $V_{\text{SS}}$       | $V_{\text{SS}}$           | $V_{\text{SS}}$        | NC               | NC               | NC  |
| <b>N</b> | NC                       | NC               | NC               | $V_{\text{SS}}$                | A                         | A                     | A                         | $V_{\text{SS}}$        | NC               | NC               | NC  |
| <b>P</b> | NC                       | NC               | DQ7              | A                              | A                         | QVLD                  | A                         | A                      | NC               | NC               | NC  |
| <b>R</b> | TDO                      | TCK              | A                | A                              | A                         | NC                    | A                         | A                      | A                | TMS              | TDI |

#### CY7C1577V18 (8M x 9)

|          | 1                        | 2                | 3                | 4                              | 5               | 6                     | 7                         | 8                      | 9                | 10               | 11  |
|----------|--------------------------|------------------|------------------|--------------------------------|-----------------|-----------------------|---------------------------|------------------------|------------------|------------------|-----|
| <b>A</b> | $\overline{\text{CQ}}$   | A                | A                | $\text{R}/\overline{\text{W}}$ | NC              | $\overline{\text{K}}$ | NC/144M                   | $\overline{\text{LD}}$ | A                | A                | CQ  |
| <b>B</b> | NC                       | NC               | NC               | A                              | NC/288M         | K                     | $\overline{\text{BWS}}_0$ | A                      | NC               | NC               | DQ3 |
| <b>C</b> | NC                       | NC               | NC               | $V_{\text{SS}}$                | A               | A                     | A                         | $V_{\text{SS}}$        | NC               | NC               | NC  |
| <b>D</b> | NC                       | NC               | NC               | $V_{\text{SS}}$                | $V_{\text{SS}}$ | $V_{\text{SS}}$       | $V_{\text{SS}}$           | $V_{\text{SS}}$        | NC               | NC               | NC  |
| <b>E</b> | NC                       | NC               | DQ4              | $V_{\text{DDQ}}$               | $V_{\text{SS}}$ | $V_{\text{SS}}$       | $V_{\text{SS}}$           | $V_{\text{DDQ}}$       | NC               | NC               | DQ2 |
| <b>F</b> | NC                       | NC               | NC               | $V_{\text{DDQ}}$               | $V_{\text{DD}}$ | $V_{\text{SS}}$       | $V_{\text{DD}}$           | $V_{\text{DDQ}}$       | NC               | NC               | NC  |
| <b>G</b> | NC                       | NC               | DQ5              | $V_{\text{DDQ}}$               | $V_{\text{DD}}$ | $V_{\text{SS}}$       | $V_{\text{DD}}$           | $V_{\text{DDQ}}$       | NC               | NC               | NC  |
| <b>H</b> | $\overline{\text{DOFF}}$ | $V_{\text{REF}}$ | $V_{\text{DDQ}}$ | $V_{\text{DDQ}}$               | $V_{\text{DD}}$ | $V_{\text{SS}}$       | $V_{\text{DD}}$           | $V_{\text{DDQ}}$       | $V_{\text{DDQ}}$ | $V_{\text{REF}}$ | ZQ  |
| <b>J</b> | NC                       | NC               | NC               | $V_{\text{DDQ}}$               | $V_{\text{DD}}$ | $V_{\text{SS}}$       | $V_{\text{DD}}$           | $V_{\text{DDQ}}$       | NC               | DQ1              | NC  |
| <b>K</b> | NC                       | NC               | NC               | $V_{\text{DDQ}}$               | $V_{\text{DD}}$ | $V_{\text{SS}}$       | $V_{\text{DD}}$           | $V_{\text{DDQ}}$       | NC               | NC               | NC  |
| <b>L</b> | NC                       | DQ6              | NC               | $V_{\text{DDQ}}$               | $V_{\text{SS}}$ | $V_{\text{SS}}$       | $V_{\text{SS}}$           | $V_{\text{DDQ}}$       | NC               | NC               | DQ0 |
| <b>M</b> | NC                       | NC               | NC               | $V_{\text{SS}}$                | $V_{\text{SS}}$ | $V_{\text{SS}}$       | $V_{\text{SS}}$           | $V_{\text{SS}}$        | NC               | NC               | NC  |
| <b>N</b> | NC                       | NC               | NC               | $V_{\text{SS}}$                | A               | A                     | A                         | $V_{\text{SS}}$        | NC               | NC               | NC  |
| <b>P</b> | NC                       | NC               | DQ7              | A                              | A               | QVLD                  | A                         | A                      | NC               | NC               | DQ8 |
| <b>R</b> | TDO                      | TCK              | A                | A                              | A               | NC                    | A                         | A                      | A                | TMS              | TDI |

#### Note

2. NC/144M and NC/288M are not connected to the die and can be tied to any voltage level.

## Pin Configuration (continued)

The pin configuration for CY7C1566V18, CY7C1577V18, CY7C1568V18, and CY7C1570V18 follow. [2]

### 165-Ball FBGA (15 x 17 x 1.4 mm) Pinout

#### CY7C1568V18 (4M x 18)

|   | 1                        | 2         | 3         | 4         | 5                         | 6                     | 7                         | 8                      | 9         | 10        | 11  |
|---|--------------------------|-----------|-----------|-----------|---------------------------|-----------------------|---------------------------|------------------------|-----------|-----------|-----|
| A | $\overline{\text{CQ}}$   | A         | A         | R/W       | $\overline{\text{BWS}}_1$ | $\overline{\text{K}}$ | NC/144M                   | $\overline{\text{LD}}$ | A         | A         | CQ  |
| B | NC                       | DQ9       | NC        | A         | NC/288M                   | K                     | $\overline{\text{BWS}}_0$ | A                      | NC        | NC        | DQ8 |
| C | NC                       | NC        | NC        | $V_{SS}$  | A                         | NC                    | A                         | $V_{SS}$               | NC        | DQ7       | NC  |
| D | NC                       | NC        | DQ10      | $V_{SS}$  | $V_{SS}$                  | $V_{SS}$              | $V_{SS}$                  | $V_{SS}$               | NC        | NC        | NC  |
| E | NC                       | NC        | DQ11      | $V_{DDQ}$ | $V_{SS}$                  | $V_{SS}$              | $V_{SS}$                  | $V_{DDQ}$              | NC        | NC        | DQ6 |
| F | NC                       | DQ12      | NC        | $V_{DDQ}$ | $V_{DD}$                  | $V_{SS}$              | $V_{DD}$                  | $V_{DDQ}$              | NC        | NC        | DQ5 |
| G | NC                       | NC        | DQ13      | $V_{DDQ}$ | $V_{DD}$                  | $V_{SS}$              | $V_{DD}$                  | $V_{DDQ}$              | NC        | NC        | NC  |
| H | $\overline{\text{DOFF}}$ | $V_{REF}$ | $V_{DDQ}$ | $V_{DDQ}$ | $V_{DD}$                  | $V_{SS}$              | $V_{DD}$                  | $V_{DDQ}$              | $V_{DDQ}$ | $V_{REF}$ | ZQ  |
| J | NC                       | NC        | NC        | $V_{DDQ}$ | $V_{DD}$                  | $V_{SS}$              | $V_{DD}$                  | $V_{DDQ}$              | NC        | DQ4       | NC  |
| K | NC                       | NC        | DQ14      | $V_{DDQ}$ | $V_{DD}$                  | $V_{SS}$              | $V_{DD}$                  | $V_{DDQ}$              | NC        | NC        | DQ3 |
| L | NC                       | DQ15      | NC        | $V_{DDQ}$ | $V_{SS}$                  | $V_{SS}$              | $V_{SS}$                  | $V_{DDQ}$              | NC        | NC        | DQ2 |
| M | NC                       | NC        | NC        | $V_{SS}$  | $V_{SS}$                  | $V_{SS}$              | $V_{SS}$                  | $V_{SS}$               | NC        | DQ1       | NC  |
| N | NC                       | NC        | DQ16      | $V_{SS}$  | A                         | A                     | A                         | $V_{SS}$               | NC        | NC        | NC  |
| P | NC                       | NC        | DQ17      | A         | A                         | QVLD                  | A                         | A                      | NC        | NC        | DQ0 |
| R | TDO                      | TCK       | A         | A         | A                         | NC                    | A                         | A                      | A         | TMS       | TDI |

#### CY7C1570V18 (2M x 36)

|   | 1                        | 2         | 3         | 4         | 5                         | 6                     | 7                         | 8                      | 9         | 10        | 11   |
|---|--------------------------|-----------|-----------|-----------|---------------------------|-----------------------|---------------------------|------------------------|-----------|-----------|------|
| A | $\overline{\text{CQ}}$   | NC/144M   | A         | R/W       | $\overline{\text{BWS}}_2$ | $\overline{\text{K}}$ | $\overline{\text{BWS}}_1$ | $\overline{\text{LD}}$ | A         | A         | CQ   |
| B | NC                       | DQ27      | DQ18      | A         | $\overline{\text{BWS}}_3$ | K                     | $\overline{\text{BWS}}_0$ | A                      | NC        | NC        | DQ8  |
| C | NC                       | NC        | DQ28      | $V_{SS}$  | A                         | NC                    | A                         | $V_{SS}$               | NC        | DQ17      | DQ7  |
| D | NC                       | DQ29      | DQ19      | $V_{SS}$  | $V_{SS}$                  | $V_{SS}$              | $V_{SS}$                  | $V_{SS}$               | NC        | NC        | DQ16 |
| E | NC                       | NC        | DQ20      | $V_{DDQ}$ | $V_{SS}$                  | $V_{SS}$              | $V_{SS}$                  | $V_{DDQ}$              | NC        | DQ15      | DQ6  |
| F | NC                       | DQ30      | DQ21      | $V_{DDQ}$ | $V_{DD}$                  | $V_{SS}$              | $V_{DD}$                  | $V_{DDQ}$              | NC        | NC        | DQ5  |
| G | NC                       | DQ31      | DQ22      | $V_{DDQ}$ | $V_{DD}$                  | $V_{SS}$              | $V_{DD}$                  | $V_{DDQ}$              | NC        | NC        | DQ14 |
| H | $\overline{\text{DOFF}}$ | $V_{REF}$ | $V_{DDQ}$ | $V_{DDQ}$ | $V_{DD}$                  | $V_{SS}$              | $V_{DD}$                  | $V_{DDQ}$              | $V_{DDQ}$ | $V_{REF}$ | ZQ   |
| J | NC                       | NC        | DQ32      | $V_{DDQ}$ | $V_{DD}$                  | $V_{SS}$              | $V_{DD}$                  | $V_{DDQ}$              | NC        | DQ13      | DQ4  |
| K | NC                       | NC        | DQ23      | $V_{DDQ}$ | $V_{DD}$                  | $V_{SS}$              | $V_{DD}$                  | $V_{DDQ}$              | NC        | DQ12      | DQ3  |
| L | NC                       | DQ33      | DQ24      | $V_{DDQ}$ | $V_{SS}$                  | $V_{SS}$              | $V_{SS}$                  | $V_{DDQ}$              | NC        | NC        | DQ2  |
| M | NC                       | NC        | DQ34      | $V_{SS}$  | $V_{SS}$                  | $V_{SS}$              | $V_{SS}$                  | $V_{SS}$               | NC        | DQ11      | DQ1  |
| N | NC                       | DQ35      | DQ25      | $V_{SS}$  | A                         | A                     | A                         | $V_{SS}$               | NC        | NC        | DQ10 |
| P | NC                       | NC        | DQ26      | A         | A                         | QVLD                  | A                         | A                      | NC        | DQ9       | DQ0  |
| R | TDO                      | TCK       | A         | A         | A                         | NC                    | A                         | A                      | A         | TMS       | TDI  |

## Pin Definitions

| Pin Name                                                                                   | IO                           | Pin Description                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                              |
|--------------------------------------------------------------------------------------------|------------------------------|----------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|
| DQ <sub>[x:0]</sub>                                                                        | Input and Output Synchronous | <b>Data Input and Output Signals.</b> Inputs are sampled on the rising edge of K and $\bar{K}$ clocks during valid write operations. These pins drive out the requested data during a read operation. Valid data is driven out on the rising edge of both the K and $\bar{K}$ clocks during read operations. When read access is deselected, Q <sub>[x:0]</sub> are automatically tri-stated.<br>CY7C1566V18 – DQ <sub>[7:0]</sub><br>CY7C1577V18 – DQ <sub>[8:0]</sub><br>CY7C1568V18 – DQ <sub>[17:0]</sub><br>CY7C1570V18 – DQ <sub>[35:0]</sub>                                                                                                                                                                                                                                                                                                                                          |
| $\bar{LD}$                                                                                 | Input Synchronous            | <b>Synchronous Load.</b> Sampled on the rising edge of the K clock. This input is brought LOW when a bus cycle sequence is defined. This definition includes address and read or write direction. All transactions operate on a burst of 2 data. LD must meet the setup and hold times around edge of K.                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                     |
| $\overline{NWS_0}$ ,<br>$\overline{NWS_1}$                                                 | Input Synchronous            | <b>Nibble Write Select 0, 1 – Active LOW (CY7C1566V18 only).</b> Sampled on the rising edge of the K and $\bar{K}$ clocks during write operations. Used to select the nibble that is written into the device during the current portion of the write operations. Nibbles not written remain unaltered.<br>$\overline{NWS_0}$ controls D <sub>[3:0]</sub> and $\overline{NWS_1}$ controls D <sub>[7:4]</sub> .<br>All the Nibble Write Selects are sampled on the same edge as the data. Deselecting a Nibble Write Select ignores the corresponding nibble of data and does not write into the device.                                                                                                                                                                                                                                                                                       |
| $\overline{BWS_0}$ ,<br>$\overline{BWS_1}$ ,<br>$\overline{BWS_2}$ ,<br>$\overline{BWS_3}$ | Input Synchronous            | <b>Byte Write Select 0, 1, 2, and 3 – Active LOW.</b> Sampled on the rising edge of the K and $\bar{K}$ clocks during write operations. Used to select which byte is written into the device during the current portion of the write operations. Bytes not written remain unaltered.<br>CY7C1577V18 – $\overline{BWS_0}$ controls D <sub>[8:0]</sub><br>CY7C1568V18 – $\overline{BWS_0}$ controls D <sub>[8:0]</sub> and $\overline{BWS_1}$ controls D <sub>[17:9]</sub> .<br>CY7C1570V18 – $\overline{BWS_0}$ controls D <sub>[8:0]</sub> , $\overline{BWS_1}$ controls D <sub>[17:9]</sub> ,<br>$\overline{BWS_2}$ controls D <sub>[26:18]</sub> and $\overline{BWS_3}$ controls D <sub>[35:27]</sub> .<br>All the Byte Write Selects are sampled on the same edge as the data. Deselecting a Byte Write Select ignores the corresponding byte of data and does not write into the device. |
| A                                                                                          | Input Synchronous            | <b>Address Inputs.</b> Sampled on the rising edge of the K clock during active read and write operations. These address inputs are multiplexed for both read and write operations. Internally, the device is organized as 8M x 8 (2 arrays each of 4M x 8) for CY7C1566V18, 8M x 9 (2 arrays each of 4M x 9) for CY7C1577V18, 4M x 18 (2 arrays each of 2M x 18) for CY7C1568V18, and 2M x 36 (2 arrays each of 1M x 36) for CY7C1570V18.                                                                                                                                                                                                                                                                                                                                                                                                                                                    |
| R/ $\bar{W}$                                                                               | Input Synchronous            | <b>Synchronous Read/Write Input.</b> When $\bar{LD}$ is LOW, this input designates the access type (read when R/ $\bar{W}$ is HIGH, write when R/ $\bar{W}$ is LOW) for loaded address. R/ $\bar{W}$ must meet the setup and hold times around edge of K.                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                    |
| QVLD                                                                                       | Valid Output Indicator       | <b>Valid Output Indicator.</b> The Q Valid indicates valid output data. QVLD is edge aligned with $\overline{CQ}$ and $\overline{CQ}$ .                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                      |
| K                                                                                          | Input Clock                  | <b>Positive Input Clock Input.</b> The rising edge of K is used to capture synchronous inputs to the device and to drive out data through Q <sub>[x:0]</sub> when in single clock mode. All accesses are initiated on the rising edge of K.                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                  |
| $\bar{K}$                                                                                  | Input Clock                  | <b>Negative Input Clock Input.</b> $\bar{K}$ is used to capture synchronous data presented to the device and to drive out data through Q <sub>[x:0]</sub> when in single clock mode.                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                         |
| CQ                                                                                         | Clock Output                 | <b>Synchronous Echo Clock Outputs.</b> This is a free running clock and is synchronized to the input clock (K) of the DDR-II+. The timing for the echo clocks is shown in <a href="#">Switching Characteristics</a> on page 23.                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                              |
| $\overline{CQ}$                                                                            | Clock Output                 | <b>Synchronous Echo Clock Outputs.</b> This is a free running clock and is synchronized to the input clock (K) of the DDR-II+. The timing for the echo clocks is shown in <a href="#">Switching Characteristics</a> on page 23.                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                              |

## Pin Definitions (continued)

| Pin Name                 | IO              | Pin Description                                                                                                                                                                                                                                                                                                                                                                                                                                                              |
|--------------------------|-----------------|------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|
| ZQ                       | Input           | <b>Output Impedance Matching Input.</b> This input is used to tune the device outputs to the system data bus impedance. CQ, $\overline{\text{CQ}}$ , and $\text{Q}_{[x:0]}$ output impedance are set to $0.2 \times \text{RQ}$ , where RQ is a resistor connected between ZQ and ground. Alternatively, this pin is connected directly to $\text{V}_{\text{DDQ}}$ that enables the minimum impedance mode. This pin is not connected directly to GND or is left unconnected. |
| $\overline{\text{DOFF}}$ | Input           | <b>DLL Turn Off – Active LOW.</b> Connecting this pin to ground turns off the DLL inside the device. The timing in the DLL turned off operation is different from that listed in this datasheet. For normal operation, this pin is connected to a pull up through a 10 Kohm or less pull up resistor. The device behaves in DDR-I mode when the DLL is turned off. In this mode, the device is operated at a frequency of up to 167 MHz with DDR-I timing.                   |
| TDO                      | Output          | <b>TDO for JTAG.</b>                                                                                                                                                                                                                                                                                                                                                                                                                                                         |
| TCK                      | Input           | <b>TCK Pin for JTAG.</b>                                                                                                                                                                                                                                                                                                                                                                                                                                                     |
| TDI                      | Input           | <b>TDI Pin for JTAG.</b>                                                                                                                                                                                                                                                                                                                                                                                                                                                     |
| TMS                      | Input           | <b>TMS Pin for JTAG.</b>                                                                                                                                                                                                                                                                                                                                                                                                                                                     |
| NC                       | N/A             | <b>Not Connected to the Die.</b> Is tied to any voltage level.                                                                                                                                                                                                                                                                                                                                                                                                               |
| NC/144M                  | N/A             | <b>Not Connected to the Die.</b> Is tied to any voltage level.                                                                                                                                                                                                                                                                                                                                                                                                               |
| NC/288M                  | N/A             | <b>Not Connected to the Die.</b> Is tied to any voltage level.                                                                                                                                                                                                                                                                                                                                                                                                               |
| $\text{V}_{\text{REF}}$  | Input Reference | <b>Reference Voltage Input.</b> Static input is used to set the reference level for HSTL inputs, outputs, and AC measurement points.                                                                                                                                                                                                                                                                                                                                         |
| $\text{V}_{\text{DD}}$   | Power Supply    | <b>Power Supply Inputs to the Core of the Device.</b>                                                                                                                                                                                                                                                                                                                                                                                                                        |
| $\text{V}_{\text{SS}}$   | Ground          | <b>Ground for the Device.</b>                                                                                                                                                                                                                                                                                                                                                                                                                                                |
| $\text{V}_{\text{DDQ}}$  | Power Supply    | <b>Power Supply Inputs for the Outputs of the Device.</b>                                                                                                                                                                                                                                                                                                                                                                                                                    |

## Functional Overview

The CY7C1566V18, CY7C1577V18, CY7C1568V18, and CY7C1570V18 are synchronous pipelined Burst SRAMs equipped with a DDR interface.

Accesses are initiated on the positive input clock (K). All synchronous input and output timing is referenced from the rising edge of the input clocks (K and  $\bar{K}$ ).

All synchronous data inputs ( $D_{[x:0]}$ ) pass through input registers controlled by the rising edge of the input clocks (K and  $\bar{K}$ ). All synchronous data outputs ( $Q_{[x:0]}$ ) pass through output registers controlled by the rising edge of the input clocks (K and  $\bar{K}$ ).

All synchronous control ( $\overline{R/W}$ ,  $\overline{LD}$ ,  $\overline{NWS}_{[x:0]}$ ,  $\overline{BWS}_{[x:0]}$ ) inputs pass through input registers controlled by the rising edge of the input clock (K).

CY7C1568V18 is described in the following sections. The same basic descriptions apply to CY7C1566V18, CY7C1577V18, and CY7C1570V18.

### Read Operations

The CY7C1568V18 is organized internally as two arrays of 2M x 18. Accesses are completed in a burst of 2 sequential 18-bit data words. Read operations are initiated by asserting  $\overline{R/W}$  HIGH and  $\overline{LD}$  LOW at the rising edge of the positive input clock (K). The address presented to the address inputs is stored in the read address register. Following the next two K clock rise, the corresponding 18-bit word of data from this address location is driven onto the  $Q_{[17:0]}$  using  $\bar{K}$  as the output timing reference. On the subsequent rising edge of K, the next 18-bit data word is driven onto the  $Q_{[17:0]}$ . The requested data is valid 0.45 ns from the rising edge of the input clock (K and  $\bar{K}$ ). To maintain the internal logic, each read access must be allowed to complete. Read accesses are initiated on every rising edge of the positive input clock (K).

When read access is deselected, the CY7C1568V18 first completes the pending read transactions. Synchronous internal circuitry automatically tri-states the output following the next rising edge of the negative input clock ( $\bar{K}$ ). This enables a seamless transition between devices without the insertion of wait states in a depth expanded memory.

### Write Operations

Write operations are initiated by asserting  $\overline{R/W}$  LOW and  $\overline{LD}$  LOW at the rising edge of the positive input clock (K). The address presented to address inputs is stored in the write address register. On the following K clock rise, the data presented to  $D_{[17:0]}$  is latched and stored into the 18-bit write data register, provided  $\overline{BWS}_{[1:0]}$  are both asserted active. On the subsequent rising edge of the negative input clock ( $\bar{K}$ ), the information presented to  $D_{[17:0]}$  is also stored into the write data register, provided  $\overline{BWS}_{[1:0]}$  are both asserted active. The 36 bits of data are then written into the memory array at the specified location. Write accesses can be initiated on every rising edge of

the positive input clock (K). Doing so pipelines the data flow such that 18 bits of data is transferred into the device on every rising edge of the input clocks (K and  $\bar{K}$ ).

When the write access is deselected, the device ignores all inputs after the pending write operations are completed.

### Byte Write Operations

Byte write operations are supported by the CY7C1568V18. A write operation is initiated as described in the [Write Operations](#) section. The bytes that are written are determined by  $\overline{BWS}_0$  and  $\overline{BWS}_1$ , which are sampled with each set of 18-bit data words. Asserting the appropriate Byte Write Select input during the data portion of a write latches the data being presented and writes it into the device. Deasserting the Byte Write Select input during the data portion of a write enables the data stored in the device for that byte to remain unaltered. This feature can be used to simplify read, modify, and or write operations to a byte write operation.

### Double Data Rate Operation

The CY7C1568V18 enables high-performance operation through high clock frequencies (achieved through pipelining) and DDR mode of operation. The CY7C1568V18 requires a minimum of two No Operation (NOP) cycles during transition from a read to a write cycle. At higher frequencies, some applications require a third NOP cycle to avoid contention.

If a read occurs after a write cycle, address and data for the write are stored in registers. The write information is stored because the SRAM cannot perform the last word write to the array without conflicting with the read. The data stays in this register until the next write cycle occurs. On the first write cycle after the read(s), the stored data from the earlier write is written into the SRAM array. This is called a Posted write.

If a read is performed on the same address on which a write is performed in the previous cycle, the SRAM reads out the most current data. The SRAM does this by bypassing the memory array and reading the data from the registers.

### Depth Expansion

Depth expansion requires replicating the  $\overline{LD}$  control signal for each bank. All other control signals can be common between banks as appropriate.

### Programmable Impedance

An external resistor, RQ, must be connected between the ZQ pin on the SRAM and  $V_{SS}$  to allow the SRAM to adjust its output driver impedance. The value of RQ must be 5x the value of the intended line impedance driven by the SRAM. The allowable range of RQ to guarantee impedance matching with a tolerance of  $\pm 15\%$ , is between 175 $\Omega$  and 350 $\Omega$ , with  $V_{DDQ} = 1.5V$ . The output impedance is adjusted every 1024 cycles upon power up to account for drifts in supply voltage and temperature.

## Echo Clocks

Echo clocks are provided on the DDR-II+ to simplify data capture on high-speed systems. Two echo clocks are generated by the DDR-II+. CQ is referenced with respect to K and CQ is referenced with respect to K. These are free-running clocks and are synchronized to the input clock of the DDR-II+. The timing for the echo clocks is shown in [Switching Characteristics](#) on page 23.

## Valid Data Indicator (QVLD)

QVLD is provided on the DDR-II+ to simplify data capture on high speed systems. The QVLD is generated by the DDR-II+ device along with data output. This signal is also edge aligned with the echo clock and follows the timing of any data pin. This signal is asserted half a cycle before valid data arrives.

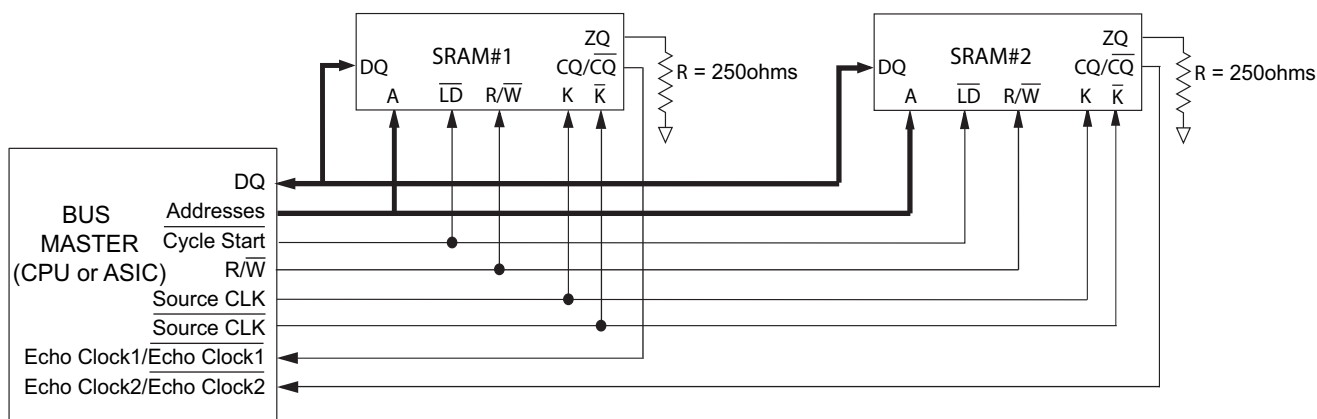
## DLL

These chips use a Delay Lock Loop (DLL) that is designed to function between 120 MHz and the specified maximum clock frequency. The DLL may be disabled by applying ground to the DOFF pin. When the DLL is turned off, the device behaves in DDR-I mode (with 1.0 cycle latency and a longer access time). For more information, refer to the application note, "DLL Considerations in QDRII/DDRII/QDRII+/DDRII+". The DLL can also be reset by slowing or stopping the input clocks K and K for a minimum of 30ns. However, it is not necessary to reset the DLL to lock to the desired frequency. During Power-up, when the DOFF is tied HIGH, the DLL gets locked after 2048 cycles of stable clock.

## Application Example

Figure 1 shows two DDR-II+ used in an application.

**Figure 1. Application Example**



## Truth Table

The truth table for CY7C1566V18, CY7C1577V18, CY7C1568V18, and CY7C1570V18 follows. [3, 4, 5, 6, 7, 8]

| Operation                                                                                                                   | K       | $\overline{\text{LD}}$ | R/ $\overline{\text{W}}$ | DQ                                               | DQ                                                 |
|-----------------------------------------------------------------------------------------------------------------------------|---------|------------------------|--------------------------|--------------------------------------------------|----------------------------------------------------|
| Write Cycle:<br>Load address; wait one cycle;<br>input write data on consecutive K and $\overline{\text{K}}$ rising edges.  | L-H     | L                      | L                        | D(A) at K(t + 1) $\uparrow$                      | D(A+1) at $\overline{\text{K}}$ (t + 1) $\uparrow$ |
| Read Cycle: (2.5 cycle Latency)<br>Load address; wait two and half cycle;<br>read data on consecutive K and K rising edges. | L-H     | L                      | H                        | Q(A) at $\overline{\text{K}}$ (t + 2) $\uparrow$ | Q(A+1) at K(t + 3) $\uparrow$                      |
| NOP: No Operation                                                                                                           | L-H     | H                      | X                        | High Z                                           | High Z                                             |
| Standby: Clock Stopped                                                                                                      | Stopped | X                      | X                        | Previous State                                   | Previous State                                     |

## Write Cycle Descriptions

The write cycle description table for CY7C1566V18 and CY7C1568V18 follows. [3, 9]

| $\overline{\text{BWS}}_0$ /<br>$\overline{\text{NWS}}_0$ | $\overline{\text{BWS}}_1$ /<br>$\overline{\text{NWS}}_1$ | K   | $\overline{\text{K}}$ | Comments                                                                                                                                                                                                                                                                                                    |
|----------------------------------------------------------|----------------------------------------------------------|-----|-----------------------|-------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|
| L                                                        | L                                                        | L-H | –                     | During the data portion of a write sequence:<br>CY7C1566V18 – both nibbles ( $\text{D}_{[7:0]}$ ) are written into the device.<br>CY7C1568V18 – both bytes ( $\text{D}_{[17:0]}$ ) are written into the device.                                                                                             |
| L                                                        | L                                                        | –   | L-H                   | During the data portion of a write sequence:<br>CY7C1566V18 – both nibbles ( $\text{D}_{[7:0]}$ ) are written into the device.<br>CY7C1568V18 – both bytes ( $\text{D}_{[17:0]}$ ) are written into the device.                                                                                             |
| L                                                        | H                                                        | L-H | –                     | During the data portion of a write sequence:<br>CY7C1566V18 – only the lower nibble ( $\text{D}_{[3:0]}$ ) is written into the device, $\text{D}_{[7:4]}$ remains unaltered.<br>CY7C1568V18 – only the lower byte ( $\text{D}_{[8:0]}$ ) is written into the device, $\text{D}_{[17:9]}$ remains unaltered. |
| L                                                        | H                                                        | –   | L-H                   | During the data portion of a write sequence:<br>CY7C1566V18 – only the lower nibble ( $\text{D}_{[3:0]}$ ) is written into the device, $\text{D}_{[7:4]}$ remains unaltered.<br>CY7C1568V18 – only the lower byte ( $\text{D}_{[8:0]}$ ) is written into the device, $\text{D}_{[17:9]}$ remains unaltered. |
| H                                                        | L                                                        | L-H | –                     | During the data portion of a write sequence:<br>CY7C1566V18 – only the upper nibble ( $\text{D}_{[7:4]}$ ) is written into the device, $\text{D}_{[3:0]}$ remains unaltered.<br>CY7C1568V18 – only the upper byte ( $\text{D}_{[17:9]}$ ) is written into the device, $\text{D}_{[8:0]}$ remains unaltered. |
| H                                                        | L                                                        | –   | L-H                   | During the data portion of a write sequence:<br>CY7C1566V18 – only the upper nibble ( $\text{D}_{[7:4]}$ ) is written into the device, $\text{D}_{[3:0]}$ remains unaltered.<br>CY7C1568V18 – only the upper byte ( $\text{D}_{[17:9]}$ ) is written into the device, $\text{D}_{[8:0]}$ remains unaltered. |
| H                                                        | H                                                        | L-H | –                     | No data is written into the devices during this portion of a write operation.                                                                                                                                                                                                                               |
| H                                                        | H                                                        | –   | L-H                   | No data is written into the devices during this portion of a write operation.                                                                                                                                                                                                                               |

### Notes

- X = "Don't Care," H = Logic HIGH, L = Logic LOW,  $\uparrow$  represents rising edge.
- Device powers up deselected with the outputs in a tri-state condition.
- "A" represents address location latched by the devices when transaction was initiated. A + 1 represents the address sequence in the burst.
- "t" represents the cycle at which a read/write operation is started. t + 1 and t + 2 are the first and second clock cycles succeeding the "t" clock cycle.
- Data inputs are registered at K and  $\overline{\text{K}}$  rising edges. Data outputs are delivered on K and  $\overline{\text{K}}$  rising edges.
- Cypress recommends that K =  $\overline{\text{K}}$  = HIGH when clock is stopped. This is not essential but permits most rapid restart by overcoming transmission line charging symmetrically.
- Is based on a write cycle is initiated per the [Write Cycle Descriptions](#) table.  $\overline{\text{NWS}}_0$ ,  $\overline{\text{NWS}}_1$ ,  $\overline{\text{BWS}}_0$ ,  $\overline{\text{BWS}}_1$ ,  $\overline{\text{BWS}}_2$ , and  $\overline{\text{BWS}}_3$  are altered on different portions of a write cycle, as long as the setup and hold requirements are met.

## Write Cycle Descriptions

The write cycle description table for CY7C1577V18 follows. [3, 9]

| $\overline{\text{BWS}}_0$ | K   | $\overline{\text{K}}$ | Comments                                                                                                        |
|---------------------------|-----|-----------------------|-----------------------------------------------------------------------------------------------------------------|
| L                         | L–H | –                     | During the data portion of a write sequence, the single byte ( $\text{D}_{[8:0]}$ ) is written into the device. |
| L                         | –   | L–H                   | During the data portion of a write sequence, the single byte ( $\text{D}_{[8:0]}$ ) is written into the device. |
| H                         | L–H | –                     | No data is written into the device during this portion of a write operation.                                    |
| H                         | –   | L–H                   | No data is written into the device during this portion of a write operation.                                    |

## Write Cycle Descriptions

The write cycle description table for CY7C1570V18 follows. [3, 9]

| $\overline{\text{BWS}}_0$ | $\overline{\text{BWS}}_1$ | $\overline{\text{BWS}}_2$ | $\overline{\text{BWS}}_3$ | K   | $\overline{\text{K}}$ | Comments                                                                                                                                                                       |
|---------------------------|---------------------------|---------------------------|---------------------------|-----|-----------------------|--------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|
| L                         | L                         | L                         | L                         | L–H | –                     | During the data portion of a write sequence, all four bytes ( $\text{D}_{[35:0]}$ ) are written into the device.                                                               |
| L                         | L                         | L                         | L                         | –   | L–H                   | During the data portion of a write sequence, all four bytes ( $\text{D}_{[35:0]}$ ) are written into the device.                                                               |
| L                         | H                         | H                         | H                         | L–H | –                     | During the data portion of a write sequence, only the lower byte ( $\text{D}_{[8:0]}$ ) is written into the device. $\text{D}_{[35:9]}$ remains unaltered.                     |
| L                         | H                         | H                         | H                         | –   | L–H                   | During the data portion of a write sequence, only the lower byte ( $\text{D}_{[8:0]}$ ) is written into the device. $\text{D}_{[35:9]}$ remains unaltered.                     |
| H                         | L                         | H                         | H                         | L–H | –                     | During the data portion of a write sequence, only the byte ( $\text{D}_{[17:9]}$ ) is written into the device. $\text{D}_{[8:0]}$ and $\text{D}_{[35:18]}$ remain unaltered.   |
| H                         | L                         | H                         | H                         | –   | L–H                   | During the data portion of a write sequence, only the byte ( $\text{D}_{[17:9]}$ ) is written into the device. $\text{D}_{[8:0]}$ and $\text{D}_{[35:18]}$ remain unaltered.   |
| H                         | H                         | L                         | H                         | L–H | –                     | During the data portion of a write sequence, only the byte ( $\text{D}_{[26:18]}$ ) is written into the device. $\text{D}_{[17:0]}$ and $\text{D}_{[35:27]}$ remain unaltered. |
| H                         | H                         | L                         | H                         | –   | L–H                   | During the data portion of a write sequence, only the byte ( $\text{D}_{[26:18]}$ ) is written into the device. $\text{D}_{[17:0]}$ and $\text{D}_{[35:27]}$ remain unaltered. |
| H                         | H                         | H                         | L                         | L–H | –                     | During the data portion of a write sequence, only the byte ( $\text{D}_{[35:27]}$ ) is written into the device. $\text{D}_{[26:0]}$ remains unaltered.                         |
| H                         | H                         | H                         | L                         | –   | L–H                   | During the data portion of a write sequence, only the byte ( $\text{D}_{[35:27]}$ ) is written into the device. $\text{D}_{[26:0]}$ remains unaltered.                         |
| H                         | H                         | H                         | H                         | L–H | –                     | No data is written into the device during this portion of a write operation.                                                                                                   |
| H                         | H                         | H                         | H                         | –   | L–H                   | No data is written into the device during this portion of a write operation.                                                                                                   |

## IEEE 1149.1 Serial Boundary Scan (JTAG)

These SRAMs incorporate a serial boundary scan Test Access Port (TAP) in the FBGA package. This part is fully compliant with IEEE Standard #1149.1-2001. The TAP operates using JEDEC standard 1.8V IO logic levels.

### Disabling the JTAG Feature

It is possible to operate the SRAM without using the JTAG feature. To disable the TAP controller, TCK must be tied LOW ( $V_{SS}$ ) to prevent clocking of the device. TDI and TMS are internally pulled up and may be unconnected. They may alternatively be connected to  $V_{DD}$  through a pull up resistor. TDO must be left unconnected. Upon power up, the device comes up in a reset state, which does not interfere with the operation of the device.

### Test Access Port—Test Clock

The test clock is used only with the TAP controller. All inputs are captured on the rising edge of TCK. All outputs are driven from the falling edge of TCK.

### Test Mode Select (TMS)

The TMS input is used to give commands to the TAP controller and is sampled on the rising edge of TCK. This pin may be left unconnected if the TAP is not used. The pin is pulled up internally, resulting in a logic HIGH level.

### Test Data-In (TDI)

The TDI pin is used to serially input information into the registers and can be connected to the input of any of the registers. The register between TDI and TDO is chosen by the instruction that is loaded into the TAP instruction register. For information about loading the instruction register, see the [TAP Controller State Diagram](#) on page 14. TDI is internally pulled up and can be unconnected if the TAP is unused in an application. TDI is connected to the most significant bit (MSB) on any register.

### Test Data-Out (TDO)

The TDO output pin is used to serially clock data out from the registers. The output is active, depending upon the current state of the TAP state machine (see [Instruction Codes](#) on page 17). The output changes on the falling edge of TCK. TDO is connected to the least significant bit (LSB) of any register.

### Performing a TAP Reset

A Reset is performed by forcing TMS HIGH ( $V_{DD}$ ) for five rising edges of TCK. This Reset does not affect the operation of the SRAM and can be performed while the SRAM is operating. At power up, the TAP is reset internally to ensure that TDO comes up in a high-Z state.

### TAP Registers

Registers are connected between the TDI and TDO pins to scan the data in and out of the SRAM test circuitry. Only one register can be selected at a time through the instruction registers. Data is serially loaded into the TDI pin on the rising edge of TCK. Data is output on the TDO pin on the falling edge of TCK.

#### Instruction Register

Three-bit instructions can be serially loaded into the instruction register. This register is loaded when it is placed between the TDI and TDO pins, as shown in [TAP Controller Block Diagram](#) on page 15. Upon power up, the instruction register is loaded with the IDCODE instruction. It is also loaded with the IDCODE instruction if the controller is placed in a reset state, as described in the previous section.

When the TAP controller is in the Capture-IR state, the two least significant bits are loaded with a binary “01” pattern to allow for fault isolation of the board level serial test path.

#### Bypass Register

To save time when serially shifting data through registers, it is sometimes advantageous to skip certain chips. The bypass register is a single-bit register that can be placed between TDI and TDO pins. This enables shifting of data through the SRAM with minimal delay. The bypass register is set LOW ( $V_{SS}$ ) when the BYPASS instruction is executed.

#### Boundary Scan Register

The boundary scan register is connected to all of the input and output pins on the SRAM. Several No Connect (NC) pins are also included in the scan register to reserve pins for higher density devices.

The boundary scan register is loaded with the contents of the RAM input and output ring when the TAP controller is in the Capture-DR state and is then placed between the TDI and TDO pins when the controller is moved to the Shift-DR state. The EXTEST, SAMPLE/PRELOAD, and SAMPLE Z instructions can be used to capture the contents of the input and output ring.

The [Boundary Scan Order](#) on page 18 shows the order in which the bits are connected. Each bit corresponds to one of the bumps on the SRAM package. The MSB of the register is connected to TDI, and the LSB is connected to TDO.

#### Identification (ID) Register

The ID register is loaded with a vendor-specific, 32-bit code during the Capture-DR state when the IDCODE command is loaded in the instruction register. The IDCODE is hardwired into the SRAM and can be shifted out when the TAP controller is in the Shift-DR state. The ID register has a vendor code and other information described in [Identification Register Definitions](#) on page 17.

### TAP Instruction Set

Eight different instructions are possible with the three-bit instruction register. All combinations are listed in [Instruction Codes](#) on page 17. Three of these instructions are listed as RESERVED and must not be used. The other five instructions are described in this section in detail.

Instructions are loaded into the TAP controller during the Shift-IR state when the instruction register is placed between TDI and TDO. During this state, instructions are shifted through the instruction register through the TDI and TDO pins. To execute the instruction once it is shifted in, the TAP controller must be moved into the Update-IR state.

#### *IDCODE*

The IDCODE instruction loads a vendor-specific, 32-bit code into the instruction register. It also places the instruction register between the TDI and TDO pins and shifts the IDCODE out of the device when the TAP controller enters the Shift-DR state. The IDCODE instruction is loaded into the instruction register at power up or whenever the TAP controller is supplied a Test-Logic-Reset state.

#### *SAMPLE Z*

The SAMPLE Z instruction connects the boundary scan register between the TDI and TDO pins when the TAP controller is in a Shift-DR state. The SAMPLE Z command puts the output bus into a High-Z state until the next command is supplied during the Update IR state.

#### *SAMPLE/PRELOAD*

SAMPLE/PRELOAD is a 1149.1 mandatory instruction. When the SAMPLE/PRELOAD instructions are loaded into the instruction register and the TAP controller is in the Capture-DR state, a snapshot of data on the input and output pins is captured in the boundary scan register.

The user must be aware that the TAP controller clock can only operate at a frequency up to 20 MHz, while the SRAM clock operates more than an order of magnitude faster. Because there is a large difference in the clock frequencies, it is possible that during the Capture-DR state, an input or output undergoes a transition. The TAP may then try to capture a signal while in transition (metastable state). This does not harm the device, but there is no guarantee as to the value that is captured. Repeatable results may not be possible.

To guarantee that the boundary scan register captures the correct value of a signal, the SRAM signal must be stabilized long enough to meet the TAP controller's capture setup plus hold times ( $t_{CS}$  and  $t_{CH}$ ). The SRAM clock input might not be captured correctly if there is no way in a design to stop (or slow) the clock during a SAMPLE/PRELOAD instruction. If this is an issue, it is still possible to capture all other signals and simply ignore the value of the CK and CK captured in the boundary scan register.

Once the data is captured, it is possible to shift out the data by putting the TAP into the Shift-DR state. This places the boundary scan register between the TDI and TDO pins.

PRELOAD places an initial data pattern at the latched parallel outputs of the boundary scan register cells before the selection of another boundary scan test operation.

The shifting of data for the SAMPLE and PRELOAD phases can occur concurrently when required, that is, while the data captured is shifted out, the preloaded data can be shifted in.

#### *BYPASS*

When the BYPASS instruction is loaded in the instruction register and the TAP is placed in a Shift-DR state, the bypass register is placed between the TDI and TDO pins. The advantage of the BYPASS instruction is that it shortens the boundary scan path when multiple devices are connected together on a board.

#### *EXTEST*

The EXTEST instruction drives the preloaded data out through the system output pins. This instruction also connects the boundary scan register for serial access between the TDI and TDO in the Shift-DR controller state.

#### *EXTEST OUTPUT BUS TRI-STATE*

IEEE Standard 1149.1 mandates that the TAP controller be able to put the output bus into a tri-state mode.

The boundary scan register has a special bit located at bit #108. When this scan cell, called the "extest output bus tri-state," is latched into the preload register during the Update-DR state in the TAP controller, it directly controls the state of the output (Q-bus) pins, when the EXTEST is entered as the current instruction. When HIGH, it enables the output buffers to drive the output bus. When LOW, this bit places the output bus into a High-Z condition.

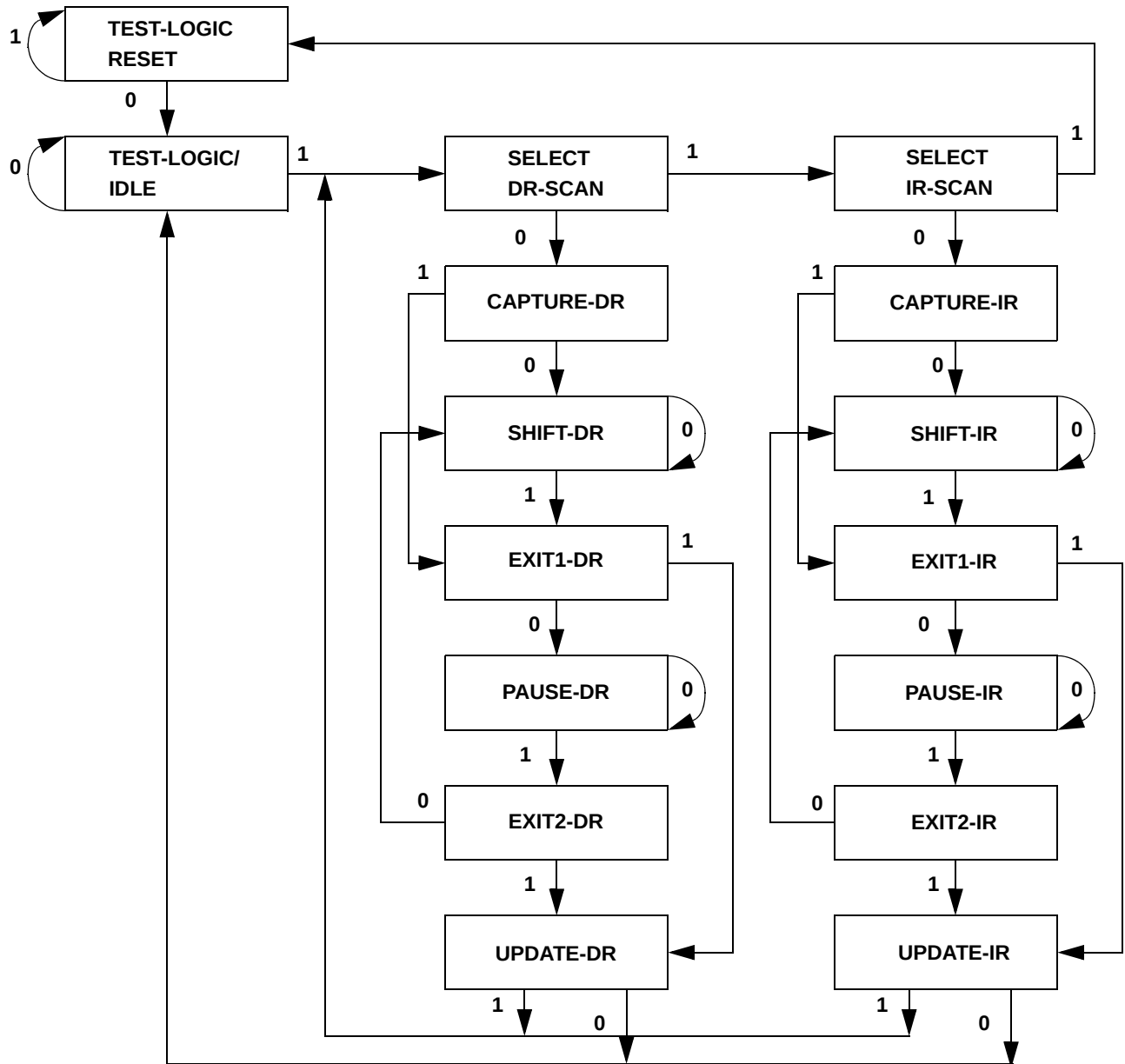
This bit can be set by entering the SAMPLE/PRELOAD or EXTEST command, and then shifting the desired bit into that cell, during the Shift-DR state. During Update-DR, the value loaded into that shift-register cell latches into the preload register. When the EXTEST instruction is entered, this bit directly controls the output Q-bus pins. Note that this bit is pre-set HIGH to enable the output when the device is powered up, and also when the TAP controller is in the Test-Logic-Reset state.

#### *Reserved*

These instructions are not implemented but are reserved for future use. Do not use these instructions.

## TAP Controller State Diagram

The state diagram for the TAP controller follows. <sup>[10]</sup>



### Note

10. The 0/1 next to each state represents the value at TMS at the rising edge of TCK.

## TAP Controller Block Diagram



## TAP Electrical Characteristics

Over the Operating Range [11, 12, 13]

| Parameter        | Description                   | Test Conditions                        | Min                 | Max                   | Unit |
|------------------|-------------------------------|----------------------------------------|---------------------|-----------------------|------|
| V <sub>OH1</sub> | Output HIGH Voltage           | I <sub>OH</sub> = -2.0 mA              | 1.4                 |                       | V    |
| V <sub>OH2</sub> | Output HIGH Voltage           | I <sub>OH</sub> = -100 µA              | 1.6                 |                       | V    |
| V <sub>OL1</sub> | Output LOW Voltage            | I <sub>OL</sub> = 2.0 mA               |                     | 0.4                   | V    |
| V <sub>OL2</sub> | Output LOW Voltage            | I <sub>OL</sub> = 100 µA               |                     | 0.2                   | V    |
| V <sub>IH</sub>  | Input HIGH Voltage            |                                        | 0.65V <sub>DD</sub> | V <sub>DD</sub> + 0.3 | V    |
| V <sub>IL</sub>  | Input LOW Voltage             |                                        | -0.3                | 0.35V <sub>DD</sub>   | V    |
| I <sub>X</sub>   | Input and Output Load Current | GND ≤ V <sub>I</sub> ≤ V <sub>DD</sub> | -5                  | 5                     | µA   |

### Notes

11. These characteristics apply to the TAP inputs (TMS, TCK, TDI, and TDO). Parallel load levels are specified in [Electrical Characteristics](#) on page 20.
12. Test conditions are specified using the load in TAP AC Test Conditions. t<sub>R</sub>/t<sub>F</sub> = 1 ns.
13. All voltage refers to ground.

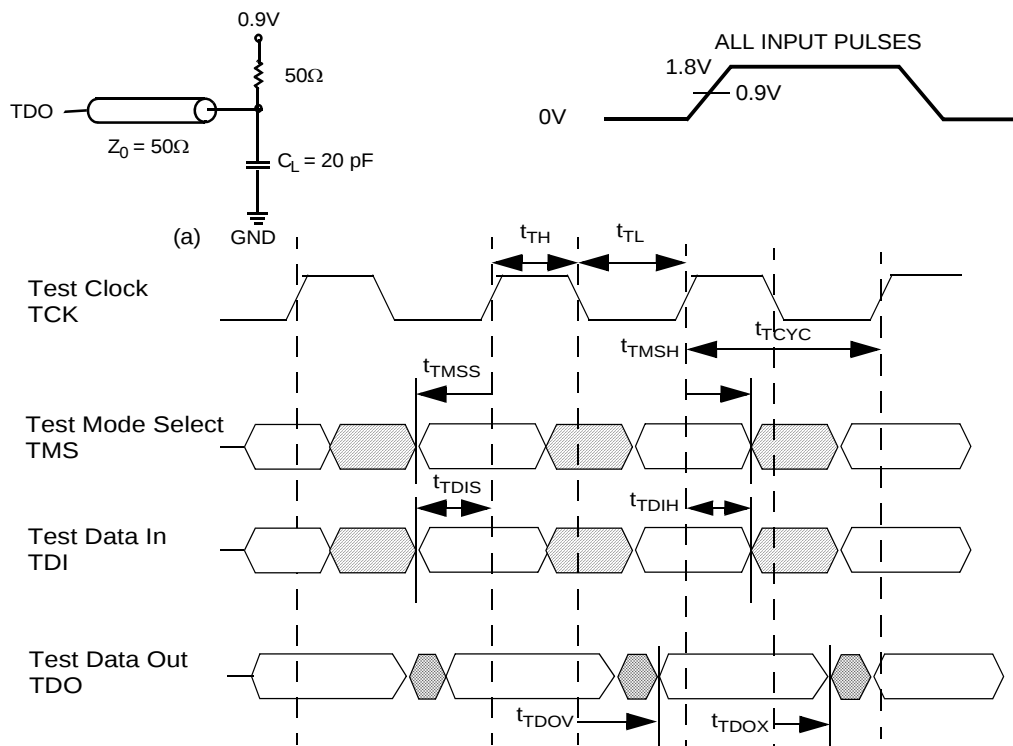
## TAP AC Switching Characteristics

Over the Operating Range [12, 14]

| Parameter           | Description                   | Min | Max | Unit |
|---------------------|-------------------------------|-----|-----|------|
| $t_{TCYC}$          | TCK Clock Cycle Time          | 50  |     | ns   |
| $t_{TF}$            | TCK Clock Frequency           |     | 20  | MHz  |
| $t_{TH}$            | TCK Clock HIGH                | 20  |     | ns   |
| $t_{TL}$            | TCK Clock LOW                 | 20  |     | ns   |
| <b>Setup Times</b>  |                               |     |     |      |
| $t_{TMSS}$          | TMS Setup to TCK Clock Rise   | 5   |     | ns   |
| $t_{TDIS}$          | TDI Setup to TCK Clock Rise   | 5   |     | ns   |
| $t_{CS}$            | Capture Setup to TCK Rise     | 5   |     | ns   |
| <b>Hold Times</b>   |                               |     |     |      |
| $t_{TMSH}$          | TMS Hold after TCK Clock Rise | 5   |     | ns   |
| $t_{TDIH}$          | TDI Hold after Clock Rise     | 5   |     | ns   |
| $t_{CH}$            | Capture Hold after Clock Rise | 5   |     | ns   |
| <b>Output Times</b> |                               |     |     |      |
| $t_{TDOV}$          | TCK Clock LOW to TDO Valid    |     | 10  | ns   |
| $t_{TDOX}$          | TCK Clock LOW to TDO Invalid  | 0   |     | ns   |

## TAP Timing and Test Conditions

Figure 2. TAP Timing and Test Conditions [12]



### Note

14.  $t_{CS}$  and  $t_{CH}$  refer to the setup and hold time requirements of latching data from the boundary scan register.

## Identification Register Definitions

| Instruction Field         | Value             |                   |                   |                   | Description                                  |
|---------------------------|-------------------|-------------------|-------------------|-------------------|----------------------------------------------|
|                           | CY7C1566V18       | CY7C1577V18       | CY7C1568V18       | CY7C1570V18       |                                              |
| Revision Number (31:29)   | 000               | 000               | 000               | 000               | Version number.                              |
| Cypress Device ID (28:12) | 11010111000000100 | 11010111000001100 | 11010111000010100 | 11010111000100100 | Defines the type of SRAM.                    |
| Cypress JEDEC ID (11:1)   | 00000110100       | 00000110100       | 00000110100       | 00000110100       | Allows unique identification of SRAM vendor. |
| ID Register Presence (0)  | 1                 | 1                 | 1                 | 1                 | Indicates the presence of an ID register.    |

## Scan Register Sizes

| Register Name | Bit Size |
|---------------|----------|
| Instruction   | 3        |
| Bypass        | 1        |
| ID            | 32       |
| Boundary Scan | 109      |

## Instruction Codes

| Instruction    | Code | Description                                                                                                                                      |
|----------------|------|--------------------------------------------------------------------------------------------------------------------------------------------------|
| EXTEST         | 000  | Captures the input and output ring contents.                                                                                                     |
| IDCODE         | 001  | Loads the ID register with the vendor ID code and places the register between TDI and TDO. This operation does not affect SRAM operation.        |
| SAMPLE Z       | 010  | Captures the input and output contents. Places the boundary scan register between TDI and TDO. Forces all SRAM output drivers to a High-Z state. |
| RESERVED       | 011  | Do Not Use: This instruction is reserved for future use.                                                                                         |
| SAMPLE/PRELOAD | 100  | Captures the input and output ring contents. Places the boundary scan register between TDI and TDO. Does not affect the SRAM operation.          |
| RESERVED       | 101  | Do Not Use: This instruction is reserved for future use.                                                                                         |
| RESERVED       | 110  | Do Not Use: This instruction is reserved for future use.                                                                                         |
| BYPASS         | 111  | Places the bypass register between TDI and TDO. This operation does not affect SRAM operation.                                                   |

## Boundary Scan Order

| Bit Number | Bump ID | Bit Number | Bump ID | Bit Number | Bump ID | Bit Number | Bump ID  |
|------------|---------|------------|---------|------------|---------|------------|----------|
| 0          | 6R      | 28         | 10G     | 56         | 6A      | 84         | 1J       |
| 1          | 6P      | 29         | 9G      | 57         | 5B      | 85         | 2J       |
| 2          | 6N      | 30         | 11F     | 58         | 5A      | 86         | 3K       |
| 3          | 7P      | 31         | 11G     | 59         | 4A      | 87         | 3J       |
| 4          | 7N      | 32         | 9F      | 60         | 5C      | 88         | 2K       |
| 5          | 7R      | 33         | 10F     | 61         | 4B      | 89         | 1K       |
| 6          | 8R      | 34         | 11E     | 62         | 3A      | 90         | 2L       |
| 7          | 8P      | 35         | 10E     | 63         | 2A      | 91         | 3L       |
| 8          | 9R      | 36         | 10D     | 64         | 1A      | 92         | 1M       |
| 9          | 11P     | 37         | 9E      | 65         | 2B      | 93         | 1L       |
| 10         | 10P     | 38         | 10C     | 66         | 3B      | 94         | 3N       |
| 11         | 10N     | 39         | 11D     | 67         | 1C      | 95         | 3M       |
| 12         | 9P      | 40         | 9C      | 68         | 1B      | 96         | 1N       |
| 13         | 10M     | 41         | 9D      | 69         | 3D      | 97         | 2M       |
| 14         | 11N     | 42         | 11B     | 70         | 3C      | 98         | 3P       |
| 15         | 9M      | 43         | 11C     | 71         | 1D      | 99         | 2N       |
| 16         | 9N      | 44         | 9B      | 72         | 2C      | 100        | 2P       |
| 17         | 11L     | 45         | 10B     | 73         | 3E      | 101        | 1P       |
| 18         | 11M     | 46         | 11A     | 74         | 2D      | 102        | 3R       |
| 19         | 9L      | 47         | 10A     | 75         | 2E      | 103        | 4R       |
| 20         | 10L     | 48         | 9A      | 76         | 1E      | 104        | 4P       |
| 21         | 11K     | 49         | 8B      | 77         | 2F      | 105        | 5P       |
| 22         | 10K     | 50         | 7C      | 78         | 3F      | 106        | 5N       |
| 23         | 9J      | 51         | 6C      | 79         | 1G      | 107        | 5R       |
| 24         | 9K      | 52         | 8A      | 80         | 1F      | 108        | Internal |
| 25         | 10J     | 53         | 7A      | 81         | 3G      |            |          |
| 26         | 11J     | 54         | 7B      | 82         | 2G      |            |          |
| 27         | 11H     | 55         | 6B      | 83         | 1H      |            |          |

## Power Up Sequence in DDR-II+ SRAM

DDR-II+ SRAMs must be powered up and initialized in a predefined manner to prevent undefined operations. During power up, when the  $\overline{\text{DOFF}}$  is tied HIGH, the DLL is locked after 2048 cycles of stable clock.

### Power Up Sequence

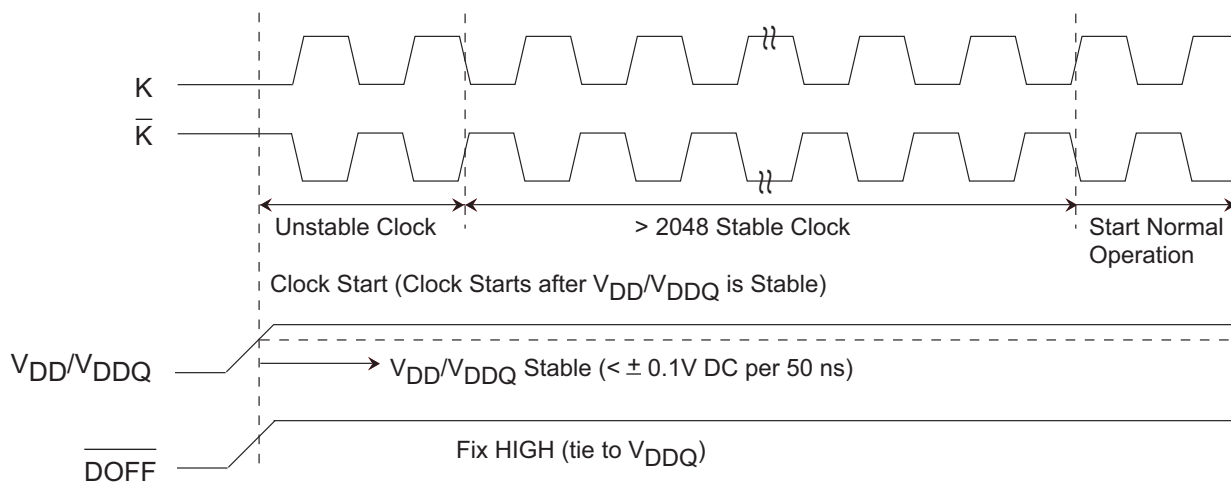
- Apply power with  $\overline{\text{DOFF}}$  tied HIGH (All other inputs can be HIGH or LOW)
  - Apply  $V_{\text{DD}}$  before  $V_{\text{DDQ}}$
  - Apply  $V_{\text{DDQ}}$  before  $V_{\text{REF}}$  or at the same time as  $V_{\text{REF}}$
- Provide stable power and clock (K,  $\overline{\text{K}}$ ) for 2048 cycles to lock the DLL.

### DLL Constraints

- DLL uses K clock as its synchronizing input. The input must have low phase jitter, which is specified as  $t_{\text{KC Var}}$ .
- The DLL functions at frequencies down to 120 MHz.
- If the input clock is unstable and the DLL is enabled, then the DLL may lock on to an incorrect frequency, causing unstable SRAM behavior. To avoid this, provide 2048 cycles stable clock to relock to the desired clock frequency.

## Power Up Waveforms

Figure 3. Power Up Waveforms



## Maximum Ratings

Exceeding maximum ratings may impair the useful life of the device. These user guidelines are not tested.

Storage Temperature .....  $-65^{\circ}\text{C}$  to  $+150^{\circ}\text{C}$   
Ambient Temperature with Power Applied..  $-55^{\circ}\text{C}$  to  $+125^{\circ}\text{C}$   
Supply Voltage on  $V_{DD}$  Relative to GND .....  $-0.5\text{V}$  to  $+2.9\text{V}$   
Supply Voltage on  $V_{DDQ}$  Relative to GND.....  $-0.5\text{V}$  to  $+V_{DD}$   
DC Applied to Outputs in High-Z .....  $-0.5\text{V}$  to  $V_{DDQ} + 0.3\text{V}$   
DC Input Voltage <sup>[15]</sup> .....  $-0.5\text{V}$  to  $V_{DD} + 0.3\text{V}$

Current into Outputs (LOW) ..... 20 mA  
Static Discharge Voltage (MIL-STD-883, M. 3015)...  $>2001\text{V}$   
Latch up Current.....  $>200\text{ mA}$

## Operating Range

| Range      | Ambient Temperature ( $T_A$ )                  | $V_{DD}$ <sup>[16]</sup> | $V_{DDQ}$ <sup>[16]</sup> |
|------------|------------------------------------------------|--------------------------|---------------------------|
| Commercial | $0^{\circ}\text{C}$ to $+70^{\circ}\text{C}$   | $1.8 \pm 0.1\text{V}$    | $1.4\text{V}$ to $V_{DD}$ |
| Industrial | $-40^{\circ}\text{C}$ to $+85^{\circ}\text{C}$ |                          |                           |

## Electrical Characteristics

Over the Operating Range <sup>[13]</sup>

### DC Electrical Characteristics

| Parameter                       | Description                             | Test Conditions                                                                                 |        |       |  | Min                        | Typ  | Max                        | Unit |
|---------------------------------|-----------------------------------------|-------------------------------------------------------------------------------------------------|--------|-------|--|----------------------------|------|----------------------------|------|
| V <sub>DD</sub>                 | Power Supply Voltage                    |                                                                                                 |        |       |  | 1.7                        | 1.8  | 1.9                        | V    |
| V <sub>DDQ</sub>                | IO Supply Voltage                       |                                                                                                 |        |       |  | 1.4                        | 1.5  | V <sub>DD</sub>            | V    |
| V <sub>OH</sub>                 | Output HIGH Voltage                     | Note 17                                                                                         |        |       |  | V <sub>DDQ</sub> /2 − 0.12 |      | V <sub>DDQ</sub> /2 + 0.12 | V    |
| V <sub>OL</sub>                 | Output LOW Voltage                      | Note 18                                                                                         |        |       |  | V <sub>DDQ</sub> /2 − 0.12 |      | V <sub>DDQ</sub> /2 + 0.12 | V    |
| V <sub>OH(LOW)</sub>            | Output HIGH Voltage                     | I <sub>OH</sub> = −0.1 mA, Nominal Impedance                                                    |        |       |  | V <sub>DDQ</sub> − 0.2     |      | V <sub>DDQ</sub>           | V    |
| V <sub>OL(LOW)</sub>            | Output LOW Voltage                      | I <sub>OL</sub> = 0.1 mA, Nominal Impedance                                                     |        |       |  | V <sub>SS</sub>            |      | 0.2                        | V    |
| V <sub>IH</sub>                 | Input HIGH Voltage                      |                                                                                                 |        |       |  | V <sub>REF</sub> + 0.1     |      | V <sub>DDQ</sub> + 0.15    | V    |
| V <sub>IL</sub>                 | Input LOW Voltage                       |                                                                                                 |        |       |  | −0.15                      |      | V <sub>REF</sub> − 0.1     | V    |
| I <sub>X</sub>                  | Input Leakage Current                   | GND ≤ V <sub>I</sub> ≤ V <sub>DDQ</sub>                                                         |        |       |  | −2                         |      | 2                          | μA   |
| I <sub>OZ</sub>                 | Output Leakage Current                  | GND ≤ V <sub>I</sub> ≤ V <sub>DDQ</sub> , Output Disabled                                       |        |       |  | −2                         |      | 2                          | μA   |
| V <sub>REF</sub>                | Input Reference Voltage <sup>[19]</sup> | Typical Value = 0.75V                                                                           |        |       |  | 0.68                       | 0.75 | 0.95                       | V    |
| I <sub>DD</sub> <sup>[20]</sup> | V <sub>DD</sub> Operating Supply        | V <sub>DD</sub> = Max,<br>I <sub>OUT</sub> = 0 mA,<br>f = f <sub>MAX</sub> = 1/t <sub>CYC</sub> | 400MHz | (x8)  |  |                            | 1400 | mA                         |      |
|                                 |                                         |                                                                                                 |        | (x9)  |  |                            | 1400 |                            |      |
|                                 |                                         |                                                                                                 |        | (x18) |  |                            | 1400 |                            |      |
|                                 |                                         |                                                                                                 |        | (x36) |  |                            | 1400 |                            |      |
|                                 |                                         |                                                                                                 | 375MHz | (x8)  |  |                            | 1300 | mA                         |      |
|                                 |                                         |                                                                                                 |        | (x9)  |  |                            | 1300 |                            |      |
|                                 |                                         |                                                                                                 |        | (x18) |  |                            | 1300 |                            |      |
|                                 |                                         |                                                                                                 |        | (x36) |  |                            | 1300 |                            |      |
|                                 |                                         |                                                                                                 | 333MHz | (x8)  |  |                            | 1200 | mA                         |      |
|                                 |                                         |                                                                                                 |        | (x9)  |  |                            | 1200 |                            |      |
|                                 |                                         |                                                                                                 |        | (x18) |  |                            | 1200 |                            |      |
|                                 |                                         |                                                                                                 |        | (x36) |  |                            | 1200 |                            |      |
|                                 |                                         |                                                                                                 | 300MHz | (x8)  |  |                            | 1100 | mA                         |      |
|                                 |                                         |                                                                                                 |        | (x9)  |  |                            | 1100 |                            |      |
|                                 |                                         |                                                                                                 |        | (x18) |  |                            | 1100 |                            |      |
|                                 |                                         |                                                                                                 |        | (x36) |  |                            | 1100 |                            |      |

### Notes

15. Overshoot:  $V_{IH(AC)} \leq V_{DDQ} + 0.3\text{V}$  (pulse width less than  $t_{CYC}/2$ ). Undershoot:  $V_{IL(AC)} \geq -0.3\text{V}$  (pulse width less than  $t_{CYC}/2$ ).  
16. Power up: assumes a linear ramp from 0V to  $V_{DD}(\text{min})$  within 200 ms. During this time  $V_{IH} < V_{DD}$  and  $V_{DDQ} \leq V_{DD}$ .  
17. Outputs are impedance controlled.  $I_{OH} = -(V_{DDQ}/2)/(RQ/5)$  for values of  $175\Omega \leq RQ \leq 350\Omega$ .  
18. Outputs are impedance controlled.  $I_{OL} = (V_{DDQ}/2)/(RQ/5)$  for values of  $175\Omega \leq RQ \leq 350\Omega$ .  
19.  $V_{REF}(\text{min}) = 0.68\text{V}$  or  $0.46V_{DDQ}$ , whichever is larger.  $V_{REF}(\text{max}) = 0.95\text{V}$  or  $0.54V_{DDQ}$ , whichever is smaller.  
20. The operation current is calculated with 50% read cycle and 50% write cycle.

## Electrical Characteristics

Over the Operating Range <sup>[13]</sup>

### DC Electrical Characteristics

| Parameter        | Description                  | Test Conditions                                                                                                                                                                           |        |       | Min | Typ | Max | Unit |
|------------------|------------------------------|-------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|--------|-------|-----|-----|-----|------|
| I <sub>SB1</sub> | Automatic Power down Current | Max V <sub>DD</sub> ,<br>Both Ports Deselected,<br>V <sub>IN</sub> ≥ V <sub>IH</sub> or V <sub>IN</sub> ≤ V <sub>IL</sub><br>f = f <sub>MAX</sub> = 1/t <sub>CYC</sub> ,<br>Inputs Static | 400MHz | (x8)  |     |     | 550 | mA   |
|                  |                              |                                                                                                                                                                                           |        | (x9)  |     |     | 550 |      |
|                  |                              |                                                                                                                                                                                           |        | (x18) |     |     | 550 |      |
|                  |                              |                                                                                                                                                                                           |        | (x36) |     |     | 550 |      |
|                  |                              |                                                                                                                                                                                           | 375MHz | (x8)  |     |     | 525 | mA   |
|                  |                              |                                                                                                                                                                                           |        | (x9)  |     |     | 525 |      |
|                  |                              |                                                                                                                                                                                           |        | (x18) |     |     | 525 |      |
|                  |                              |                                                                                                                                                                                           |        | (x36) |     |     | 525 |      |
|                  |                              |                                                                                                                                                                                           | 333MHz | (x8)  |     |     | 500 | mA   |
|                  |                              |                                                                                                                                                                                           |        | (x9)  |     |     | 500 |      |
|                  |                              |                                                                                                                                                                                           |        | (x18) |     |     | 500 |      |
|                  |                              |                                                                                                                                                                                           |        | (x36) |     |     | 500 |      |
|                  |                              |                                                                                                                                                                                           | 300MHz | (x8)  |     |     | 450 | mA   |
|                  |                              |                                                                                                                                                                                           |        | (x9)  |     |     | 450 |      |
|                  |                              |                                                                                                                                                                                           |        | (x18) |     |     | 450 |      |
|                  |                              |                                                                                                                                                                                           |        | (x36) |     |     | 450 |      |

### AC Electrical Characteristics

Over the Operating Range <sup>[15]</sup>

| Parameter       | Description        | Test Conditions | Min                    | Typ | Max                     | Unit |
|-----------------|--------------------|-----------------|------------------------|-----|-------------------------|------|
| V <sub>IH</sub> | Input HIGH Voltage |                 | V <sub>REF</sub> + 0.2 | –   | V <sub>DDQ</sub> + 0.24 | V    |
| V <sub>IL</sub> | Input LOW Voltage  |                 | –0.24                  | –   | V <sub>REF</sub> – 0.2  | V    |

## Capacitance

Tested initially and after any design or process change that may affect these parameters.

| Parameter        | Description             | Test Conditions                                                                   | Max | Unit |
|------------------|-------------------------|-----------------------------------------------------------------------------------|-----|------|
| C <sub>IN</sub>  | Input Capacitance       | T <sub>A</sub> = 25°C, f = 1 MHz, V <sub>DD</sub> = 1.8V, V <sub>DDQ</sub> = 1.5V | 5.5 | pF   |
| C <sub>CLK</sub> | Clock Input Capacitance |                                                                                   | 8.5 | pF   |
| C <sub>O</sub>   | Output Capacitance      |                                                                                   | 8   | pF   |

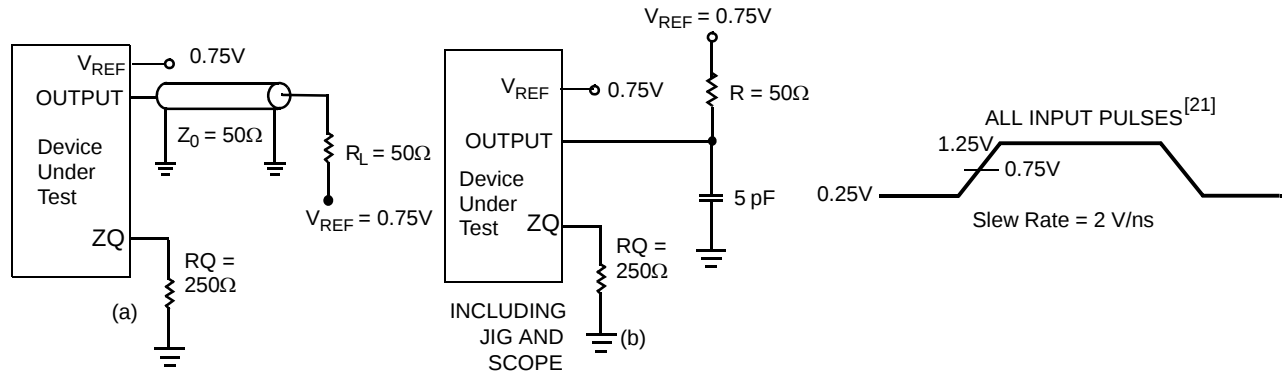
## Thermal Resistance

Tested initially and after any design or process change that may affect these parameters.

| Parameter       | Description                              | Test Conditions                                                                                                             | 165 FBGA Package | Unit |
|-----------------|------------------------------------------|-----------------------------------------------------------------------------------------------------------------------------|------------------|------|
| Θ <sub>JA</sub> | Thermal Resistance (Junction to Ambient) | Test conditions follow standard test methods and procedures for measuring thermal impedance, in accordance with EIA/JESD51. | 11.82            | °C/W |
| Θ <sub>JC</sub> | Thermal Resistance (Junction to Case)    |                                                                                                                             | 2.33             | °C/W |

## AC Test Loads and Waveforms

Figure 4. AC Test Loads and Waveforms



### Note

21. Unless otherwise noted, test conditions assume signal transition time of 2V/ns, timing reference levels of 0.75V,  $V_{REF} = 0.75V$ ,  $R_Q = 250\Omega$ ,  $V_{DDQ} = 1.5V$ , input pulse levels of 0.25V to 1.25V, output loading of the specified  $I_{OL}/I_{OH}$ , and load capacitance shown in (a) of [AC Test Loads and Waveforms](#).

## Switching Characteristics

Over the Operating Range <sup>[21, 22]</sup>

| Cypress Parameter     | Consortium Parameter  | Description                                                                                                                       | 400 MHz |      | 375 MHz |      | 333 MHz |      | 300 MHz |      | Unit             |
|-----------------------|-----------------------|-----------------------------------------------------------------------------------------------------------------------------------|---------|------|---------|------|---------|------|---------|------|------------------|
|                       |                       |                                                                                                                                   | Min     | Max  | Min     | Max  | Min     | Max  | Min     | Max  |                  |
| t <sub>POWER</sub>    |                       | V <sub>DD</sub> (Typical) to the First Access <sup>[23]</sup>                                                                     | 1       | –    | 1       | –    | 1       | –    | 1       | –    | ms               |
| t <sub>CYC</sub>      | t <sub>KHKH</sub>     | K Clock Cycle Time                                                                                                                | 2.50    | 8.40 | 2.66    | 8.40 | 3.0     | 8.40 | 3.3     | 8.40 | ns               |
| t <sub>KH</sub>       | t <sub>KHKL</sub>     | Input Clock (K/K) HIGH                                                                                                            | 0.4     | –    | 0.4     | –    | 0.4     | –    | 0.4     | –    | t <sub>CYC</sub> |
| t <sub>KL</sub>       | t <sub>KLKH</sub>     | Input Clock (K/K) LOW                                                                                                             | 0.4     | –    | 0.4     | –    | 0.4     | –    | 0.4     | –    | t <sub>CYC</sub> |
| t <sub>KHKH</sub>     | t <sub>KHKH</sub>     | K Clock Rise to K Clock Rise (rising edge to rising edge)                                                                         | 1.06    | –    | 1.13    | –    | 1.28    | –    | 1.40    | –    | ns               |
| <b>Setup Times</b>    |                       |                                                                                                                                   |         |      |         |      |         |      |         |      |                  |
| t <sub>SA</sub>       | t <sub>AVKH</sub>     | Address Setup to K Clock Rise                                                                                                     | 0.4     | –    | 0.4     | –    | 0.4     | –    | 0.4     | –    | ns               |
| t <sub>SC</sub>       | t <sub>IVKH</sub>     | Control Setup to K Clock Rise ( $\overline{\text{LD}}$ , $\overline{\text{R/W}}$ )                                                | 0.4     | –    | 0.4     | –    | 0.4     | –    | 0.4     | –    | ns               |
| t <sub>SCDDR</sub>    | t <sub>IVKH</sub>     | Double Data Rate Control Setup to Clock (K/K) Rise (BWS <sub>0</sub> , BWS <sub>1</sub> , BWS <sub>2</sub> , BWS <sub>3</sub> )   | 0.28    | –    | 0.28    | –    | 0.28    | –    | 0.28    | –    | ns               |
| t <sub>SD</sub>       | t <sub>DVKH</sub>     | D <sub>[X:0]</sub> Setup to Clock (K/K) Rise                                                                                      | 0.28    | –    | 0.28    | –    | 0.28    | –    | 0.28    | –    | ns               |
| <b>Hold Times</b>     |                       |                                                                                                                                   |         |      |         |      |         |      |         |      |                  |
| t <sub>HA</sub>       | t <sub>KHAX</sub>     | Address Hold after K Clock Rise                                                                                                   | 0.4     | –    | 0.4     | –    | 0.4     | –    | 0.4     | –    | ns               |
| t <sub>HC</sub>       | t <sub>KHIX</sub>     | Control Hold after K Clock Rise ( $\overline{\text{LD}}$ , $\overline{\text{R/W}}$ )                                              | 0.4     | –    | 0.4     | –    | 0.4     | –    | 0.4     | –    | ns               |
| t <sub>HCDDR</sub>    | t <sub>KHIX</sub>     | Double Data Rate Control Hold after Clock (K/K) Rise (BWS <sub>0</sub> , BWS <sub>1</sub> , BWS <sub>2</sub> , BWS <sub>3</sub> ) | 0.28    | –    | 0.28    | –    | 0.28    | –    | 0.28    | –    | ns               |
| t <sub>HD</sub>       | t <sub>KHDX</sub>     | D <sub>[X:0]</sub> Hold after Clock (K/K) Rise                                                                                    | 0.28    | –    | 0.28    | –    | 0.28    | –    | 0.28    | –    | ns               |
| <b>Output Times</b>   |                       |                                                                                                                                   |         |      |         |      |         |      |         |      |                  |
| t <sub>CO</sub>       | t <sub>CHQV</sub>     | K/K Clock Rise to Data Valid                                                                                                      | –       | 0.45 | –       | 0.45 | –       | 0.45 | –       | 0.45 | ns               |
| t <sub>DOH</sub>      | t <sub>CHQX</sub>     | Data Output Hold after K/K Clock Rise (Active to Active)                                                                          | –0.45   | –    | –0.45   | –    | –0.45   | –    | –0.45   | –    | ns               |
| t <sub>CCQO</sub>     | t <sub>CHCQV</sub>    | K/K Clock Rise to Echo Clock Valid                                                                                                | –       | 0.45 | –       | 0.45 | –       | 0.45 | –       | 0.45 | ns               |
| t <sub>CQOH</sub>     | t <sub>CHCQX</sub>    | Echo Clock Hold after K/K Clock Rise                                                                                              | –0.45   | –    | –0.45   | –    | –0.45   | –    | –0.45   | –    | ns               |
| t <sub>CQD</sub>      | t <sub>CQHCV</sub>    | Echo Clock High to Data Valid                                                                                                     | –       | 0.2  | –       | 0.2  | –       | 0.2  | –       | 0.2  | ns               |
| t <sub>CQDOH</sub>    | t <sub>CQHCV</sub>    | Echo Clock High to Data Invalid                                                                                                   | –0.2    | –    | –0.2    | –    | –0.2    | –    | –0.2    | –    | ns               |
| t <sub>CQH</sub>      | t <sub>CQHCQL</sub>   | Output Clock (CQ/CQ) HIGH <sup>[24]</sup>                                                                                         | 0.81    | –    | 0.88    | –    | 1.03    | –    | 1.15    | –    | ns               |
| t <sub>CQHCH</sub>    | t <sub>CQHCH</sub>    | CQ Clock Rise to CQ Clock Rise <sup>[24]</sup> (rising edge to rising edge)                                                       | 0.81    | –    | 0.88    | –    | 1.03    | –    | 1.15    | –    | ns               |
| t <sub>CHZ</sub>      | t <sub>CHQZ</sub>     | Clock (K/K) Rise to High-Z (Active to High Z) <sup>[25, 26]</sup>                                                                 | –       | 0.45 | –       | 0.45 | –       | 0.45 | –       | 0.45 | ns               |
| t <sub>CLZ</sub>      | t <sub>CHQX1</sub>    | Clock (K/K) Rise to Low-Z <sup>[25, 26]</sup>                                                                                     | –0.45   | –    | –0.45   | –    | –0.45   | –    | –0.45   | –    | ns               |
| t <sub>QVLD</sub>     | t <sub>QVLD</sub>     | Echo Clock High to QVLD Valid <sup>[27]</sup>                                                                                     | –0.20   | 0.20 | –0.20   | 0.20 | –0.20   | 0.20 | –0.20   | 0.20 | ns               |
| <b>DLL Timing</b>     |                       |                                                                                                                                   |         |      |         |      |         |      |         |      |                  |
| t <sub>KC Var</sub>   | t <sub>KC Var</sub>   | Clock Phase Jitter                                                                                                                | –       | 0.20 | –       | 0.20 | –       | 0.20 | –       | 0.20 | ns               |
| t <sub>KC lock</sub>  | t <sub>KC lock</sub>  | DLL Lock Time (K)                                                                                                                 | 2048    | –    | 2048    | –    | 2048    | –    | 2048    | –    | Cycles           |
| t <sub>KC Reset</sub> | t <sub>KC Reset</sub> | K Static to DLL Reset <sup>[28]</sup>                                                                                             | 30      | –    | 30      | –    | 30      | –    | 30      | –    | ns               |

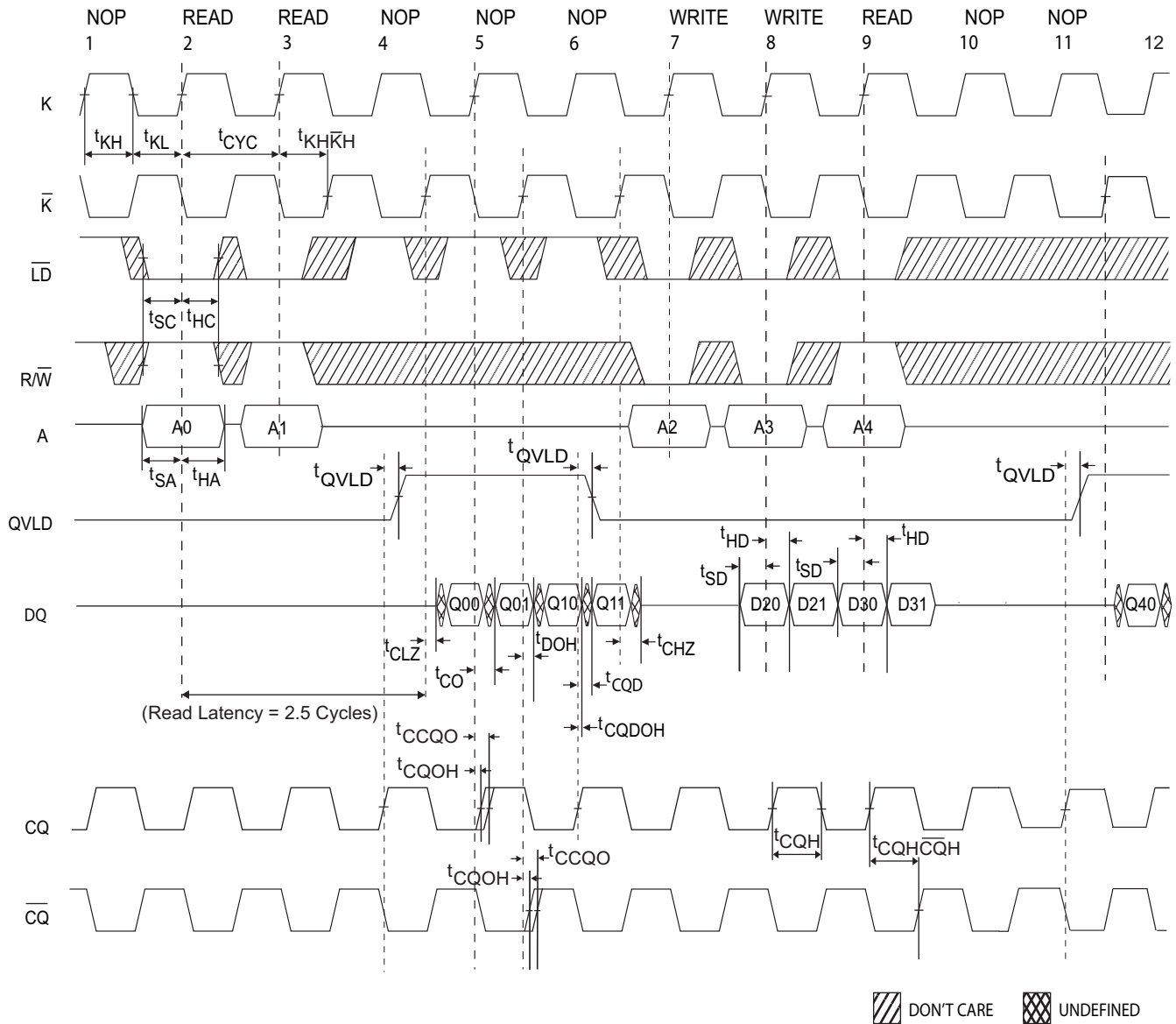
### Notes

22. When a part with a maximum frequency above 300 MHz is operating at a lower clock frequency, it requires the input timings of the frequency range in which it is operated and outputs data with the output timings of that frequency range.
23. This part has a voltage regulator internally; t<sub>POWER</sub> is the time that the power is supplied above V<sub>DD</sub> minimum initially before a read or write operation is initiated.
24. These parameters are extrapolated from the input timing parameters (t<sub>KHKH</sub> - 250 ps, where 250 ps is the internal jitter. An input jitter of 200 ps (t<sub>KC Var</sub>) is already included in the t<sub>KHKH</sub>). These parameters are only guaranteed by design and are not tested in production.
25. t<sub>CHZ</sub>, t<sub>CLZ</sub>, are specified with a load capacitance of 5 pF as in (b) of "AC Test Loads and Waveforms" on page 22. Transition is measured ±100 mV from steady state voltage.
26. At any given voltage and temperature, t<sub>CHZ</sub> is less than t<sub>CLZ</sub> and t<sub>CHZ</sub> less than t<sub>CO</sub>.
27. t<sub>QVLD</sub> specification is applicable for both rising and falling edges of QVLD signal.
28. Hold to >V<sub>IH</sub> or <V<sub>IL</sub>.

## Switching Waveforms

### Read/Write/Deselect Sequence [29, 30, 31]

**Figure 5. Waveform for 2.5 Cycle Read Latency**



#### Notes

29. Q00 refers to output from address A0. Q01 refers to output from the next internal burst address following A0, that is, A0 + 1.

30. Outputs are disabled (High Z) one clock cycle after a NOP.

31. In this example, if address A4 = A3, then data Q40 = D30 and Q41 = D31. Write data is forwarded immediately as read results. This note applies to the whole diagram.

## Ordering Information

Not all of the speed, package, and temperature ranges are available. Contact your local sales representative or visit [www.cypress.com](http://www.cypress.com) for actual products offered.

| Speed (MHz) | Ordering Code       | Package Diagram | Package Type                                                   | Operating Range |
|-------------|---------------------|-----------------|----------------------------------------------------------------|-----------------|
| 400         | CY7C1566V18-400BZC  | 51-85195        | 165-Ball Fine Pitch Ball Grid Array (15 x 17 x 1.4 mm)         | Commercial      |
|             | CY7C1577V18-400BZC  |                 |                                                                |                 |
|             | CY7C1568V18-400BZC  |                 |                                                                |                 |
|             | CY7C1570V18-400BZC  |                 |                                                                |                 |
|             | CY7C1566V18-400BZXC | 51-85195        | 165-Ball Fine Pitch Ball Grid Array (15 x 17 x 1.4 mm) Pb-Free |                 |
|             | CY7C1577V18-400BZXC |                 |                                                                |                 |
|             | CY7C1568V18-400BZXC |                 |                                                                |                 |
|             | CY7C1570V18-400BZXC |                 |                                                                |                 |
|             | CY7C1566V18-400BZI  | 51-85195        | 165-Ball Fine Pitch Ball Grid Array (15 x 17 x 1.4 mm)         | Industrial      |
|             | CY7C1577V18-400BZI  |                 |                                                                |                 |
|             | CY7C1568V18-400BZI  |                 |                                                                |                 |
|             | CY7C1570V18-400BZI  |                 |                                                                |                 |
|             | CY7C1566V18-400BZXI | 51-85195        | 165-Ball Fine Pitch Ball Grid Array (15 x 17 x 1.4 mm) Pb-Free |                 |
|             | CY7C1577V18-400BZXI |                 |                                                                |                 |
|             | CY7C1568V18-400BZXI |                 |                                                                |                 |
|             | CY7C1570V18-400BZXI |                 |                                                                |                 |
| 375         | CY7C1566V18-375BZC  | 51-85195        | 165-Ball Fine Pitch Ball Grid Array (15 x 17 x 1.4 mm)         | Commercial      |
|             | CY7C1577V18-375BZC  |                 |                                                                |                 |
|             | CY7C1568V18-375BZC  |                 |                                                                |                 |
|             | CY7C1570V18-375BZC  |                 |                                                                |                 |
|             | CY7C1566V18-375BZXC | 51-85195        | 165-Ball Fine Pitch Ball Grid Array (15 x 17 x 1.4 mm) Pb-Free |                 |
|             | CY7C1577V18-375BZXC |                 |                                                                |                 |
|             | CY7C1568V18-375BZXC |                 |                                                                |                 |
|             | CY7C1570V18-375BZXC |                 |                                                                |                 |
|             | CY7C1566V18-375BZI  | 51-85195        | 165-Ball Fine Pitch Ball Grid Array (15 x 17 x 1.4 mm)         | Industrial      |
|             | CY7C1577V18-375BZI  |                 |                                                                |                 |
|             | CY7C1568V18-375BZI  |                 |                                                                |                 |
|             | CY7C1570V18-375BZI  |                 |                                                                |                 |
|             | CY7C1566V18-375BZXI | 51-85195        | 165-Ball Fine Pitch Ball Grid Array (15 x 17 x 1.4 mm) Pb-Free |                 |
|             | CY7C1577V18-375BZXI |                 |                                                                |                 |
|             | CY7C1568V18-375BZXI |                 |                                                                |                 |
|             | CY7C1570V18-375BZXI |                 |                                                                |                 |

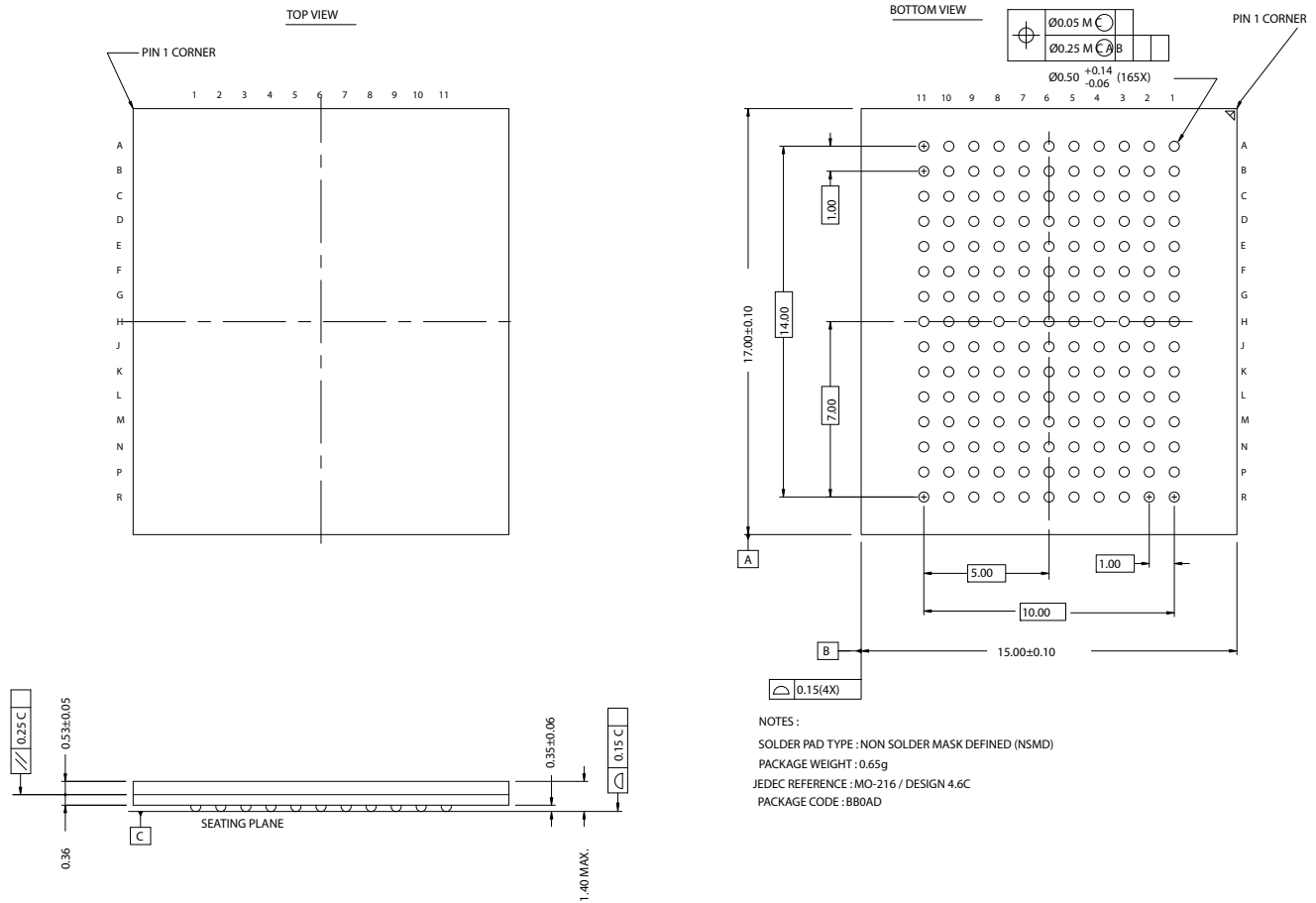
## Ordering Information (continued)

Not all of the speed, package, and temperature ranges are available. Contact your local sales representative or visit [www.cypress.com](http://www.cypress.com) for actual products offered.

| Speed (MHz) | Ordering Code       | Package Diagram | Package Type                                                   | Operating Range |
|-------------|---------------------|-----------------|----------------------------------------------------------------|-----------------|
| 333         | CY7C1566V18-333BZC  | 51-85195        | 165-Ball Fine Pitch Ball Grid Array (15 x 17 x 1.4 mm)         | Commercial      |
|             | CY7C1577V18-333BZC  |                 |                                                                |                 |
|             | CY7C1568V18-333BZC  |                 |                                                                |                 |
|             | CY7C1570V18-333BZC  |                 |                                                                |                 |
|             | CY7C1566V18-333BZXC | 51-85195        | 165-Ball Fine Pitch Ball Grid Array (15 x 17 x 1.4 mm) Pb-Free |                 |
|             | CY7C1577V18-333BZXC |                 |                                                                |                 |
|             | CY7C1568V18-333BZXC |                 |                                                                |                 |
|             | CY7C1570V18-333BZXC |                 |                                                                |                 |
|             | CY7C1566V18-333BZI  | 51-85195        | 165-Ball Fine Pitch Ball Grid Array (15 x 17 x 1.4 mm)         | Industrial      |
|             | CY7C1577V18-333BZI  |                 |                                                                |                 |
|             | CY7C1568V18-333BZI  |                 |                                                                |                 |
|             | CY7C1570V18-333BZI  |                 |                                                                |                 |
|             | CY7C1566V18-333BZXI | 51-85195        | 165-Ball Fine Pitch Ball Grid Array (15 x 17 x 1.4 mm) Pb-Free |                 |
|             | CY7C1577V18-333BZXI |                 |                                                                |                 |
|             | CY7C1568V18-333BZXI |                 |                                                                |                 |
|             | CY7C1570V18-333BZXI |                 |                                                                |                 |
| 300         | CY7C1566V18-300BZC  | 51-85195        | 165-Ball Fine Pitch Ball Grid Array (15 x 17 x 1.4 mm)         | Commercial      |
|             | CY7C1577V18-300BZC  |                 |                                                                |                 |
|             | CY7C1568V18-300BZC  |                 |                                                                |                 |
|             | CY7C1570V18-300BZC  |                 |                                                                |                 |
|             | CY7C1566V18-300BZXC | 51-85195        | 165-Ball Fine Pitch Ball Grid Array (15 x 17 x 1.4 mm) Pb-Free |                 |
|             | CY7C1577V18-300BZXC |                 |                                                                |                 |
|             | CY7C1568V18-300BZXC |                 |                                                                |                 |
|             | CY7C1570V18-300BZXC |                 |                                                                |                 |
|             | CY7C1566V18-300BZI  | 51-85195        | 165-Ball Fine Pitch Ball Grid Array (15 x 17 x 1.4 mm)         | Industrial      |
|             | CY7C1577V18-300BZI  |                 |                                                                |                 |
|             | CY7C1568V18-300BZI  |                 |                                                                |                 |
|             | CY7C1570V18-300BZI  |                 |                                                                |                 |
|             | CY7C1566V18-300BZXI | 51-85195        | 165-Ball Fine Pitch Ball Grid Array (15 x 17 x 1.4 mm) Pb-Free |                 |
|             | CY7C1577V18-300BZXI |                 |                                                                |                 |
|             | CY7C1568V18-300BZXI |                 |                                                                |                 |
|             | CY7C1570V18-300BZXI |                 |                                                                |                 |

## Package Diagram

**Figure 6. 165-Ball FBGA (15 x 17 x 1.4 mm)**



51-85195-\*A

## Document History Page

| Document Title: CY7C1566V18/CY7C1577V18/CY7C1568V18/CY7C1570V18, 72-Mbit DDR-II+ SRAM 2-Word Burst Architecture (2.5 Cycle Read Latency)<br>Document Number: 001-06551 |         |            |                 |                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                      |
|------------------------------------------------------------------------------------------------------------------------------------------------------------------------|---------|------------|-----------------|------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|
| REV.                                                                                                                                                                   | ECN No. | Issue Date | Orig. of Change | Description of Change                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                |
| **                                                                                                                                                                     | 432718  | See ECN    | NXR             | New datasheet                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                        |
| *A                                                                                                                                                                     | 437000  | See ECN    | IGS             | ECN to show on web                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                   |
| *B                                                                                                                                                                     | 461934  | See ECN    | NXR             | Changed $t_{TH}$ and $t_{TL}$ from 40 ns to 20 ns, changed $t_{TMSS}$ , $t_{TDIS}$ , $t_{CS}$ , $t_{TMSH}$ , $t_{TDIH}$ , $t_{CH}$ from 10 ns to 5 ns, and changed $t_{TDOV}$ from 20 ns to 10 ns in TAP AC Switching Characteristics table<br>Modified power up waveform                                                                                                                                                                                                                                                                                                                                                                                                                                                                            |
| *C                                                                                                                                                                     | 497567  | See ECN    | NXR             | Changed the $V_{DDQ}$ operating voltage to 1.4V to $V_{DD}$ in the Features section, Operating Range table, and the DC Electrical Characteristics table<br>Added foot note in page 1<br>Changed the Maximum rating of ambient temperature with power applied from $-10^{\circ}\text{C}$ to $+85^{\circ}\text{C}$ to $-55^{\circ}\text{C}$ to $+125^{\circ}\text{C}$<br>Changed $V_{REF}$ (Max) specification from 0.85V to 0.95V in the DC Electrical Characteristics table and in the note below the table<br>Updated footnote 18 to specify overshoot and undershoot specification<br>Updated $I_{DD}$ and $I_{SB}$ values<br>Updated $\theta_{JA}$ and $\theta_{JC}$ values<br>Removed x9 part and its related information<br>Updated footnote 25 |
| *D                                                                                                                                                                     | 1351504 | See ECN    | VKN/AESA        | Converted from preliminary to final<br>Added x8 and x9 parts<br>Updated logic block diagram for x18 and x36 parts<br>Changed $t_{CYC}$ max spec to 8.4 ns for all speed bins<br>Updated footnote# 21<br>Updated Ordering Information table                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                           |
| *E                                                                                                                                                                     | 2193266 | See ECN    | VKN/AESA        | Added footnote# 20 related to $I_{DD}$                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                               |

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